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MAX14906

Quad-Channel Industrial Digital Output/Digital Input

General Description

The MAX14906 is an IEC 61131-2 compliant, high-speed, four-channel industrial digital output, digital input device that can be configured on a per-channel basis as a high-side (HS) switch, push-pull (PP) driver, or a Type 1 and 3, or Type 2 digital input. The MAX14906 is specified for operation with a supply voltage up to 40V and is tolerant to 65V.

The high-side switch current limiting is settable from 130mA to 1.2A with the option of 2x load inrush current. The high-side driver on-resistance is 120mΩ (typ) at 25°C ambient temperature. Optional push-pull operation allows high speed driving of cables and fast discharge of load capacitance. For digital input operation, current sinks for 2.3mA (Type 1 and 3) or 7mA (Type 2) are provided.

The SPI interface has a built-in chip addressing decoder, allowing communication with multiple MAX14906 devices utilizing a shared SPI with a common chip select (\overline{CS}). The SPI interface provides flexibility for global and per-channel configuration and diagnostics, including supply over-voltage and undervoltage detection, wire-break or open-wire detection, thermal overload and current limit reporting, and more. For high-speed operation, the digital input and output states can be monitored and changed directly using pins for increased system speed and throughput.

Open-wire detection monitors open-wire/open-load conditions with switches in the off state. LED drivers provide indication of per-channel fault, status, and supply undervoltage conditions. Internal active clamps allow for fast turn-off of inductive loads. Integrated line-to-ground and line-to-line surge protection only requires a TVS on V_{DD} .

The MAX14906 is available in a compact 48-pin 7mm x 7mm QFN package.

Applications

- Industrial Digital Output and Input Module
- Configurable Digital Input/Output
- Motor Control
- PLC Systems
- Distributed Control Systems (DCS)

Benefits and Features

- Per-Channel Configurability Enables Wide Range of Applications
 - Digital Output: High-Side (HS) Switch or Push-Pull (PP) Driver
 - Digital Input: Software Selectable Type 1 and 3, or Type 2
 - Current Limit Settable from 130mA to 1.2A
 - Serial (SPI) or Direct Operation Using Pins
 - Independent Channel Powering
- Fault Tolerant with Built-In Diagnostics
 - Per-Channel Diagnostics
 - Integrated Voltage Supply Monitoring and Short-to- V_{DD} Detection
 - Open-Wire/Open-Load Detection
 - Thermal Shutdown Protection
 - Watchdog Timer
 - 5-Bit CRC Code Generation and Checking for SPI Error Detection
- High Integration Reduces BOM Count and PCB Space
 - Integrated LDO Compatible with 5V Logic Devices
 - Internal Active Clamps for Fast Inductive Load Turn-Off
 - 0.6μs (typ) DO and 1μs (typ) DI Propagation Delays
 - Addressable SPI
 - 7mm x 7mm TQFN Package
- Reduced Power and Heat Dissipation
 - Low $R_{DS(ON)}$ for High-Side Switches, 120mΩ (typ)
 - Accurate Output Current Limiting
 - Accurate Input Current Sinks, Type 1 and 3, or Type 2
- Robust Design
 - 10V to 40V Operating Supply Range, 65V Tolerant
 - SafeDemag™ Allows Fast Turn-Off of Unlimited Inductance
 - ±16kV Air-Gap ESD and ±8kV Contact ESD
 - ±1kV Surge Tolerant Using TVS Protection on V_{DD} to GND
 - -40°C to +125°C Operating Temperature

SafeDemag is a trademark of Maxim Integrated Products, Inc.

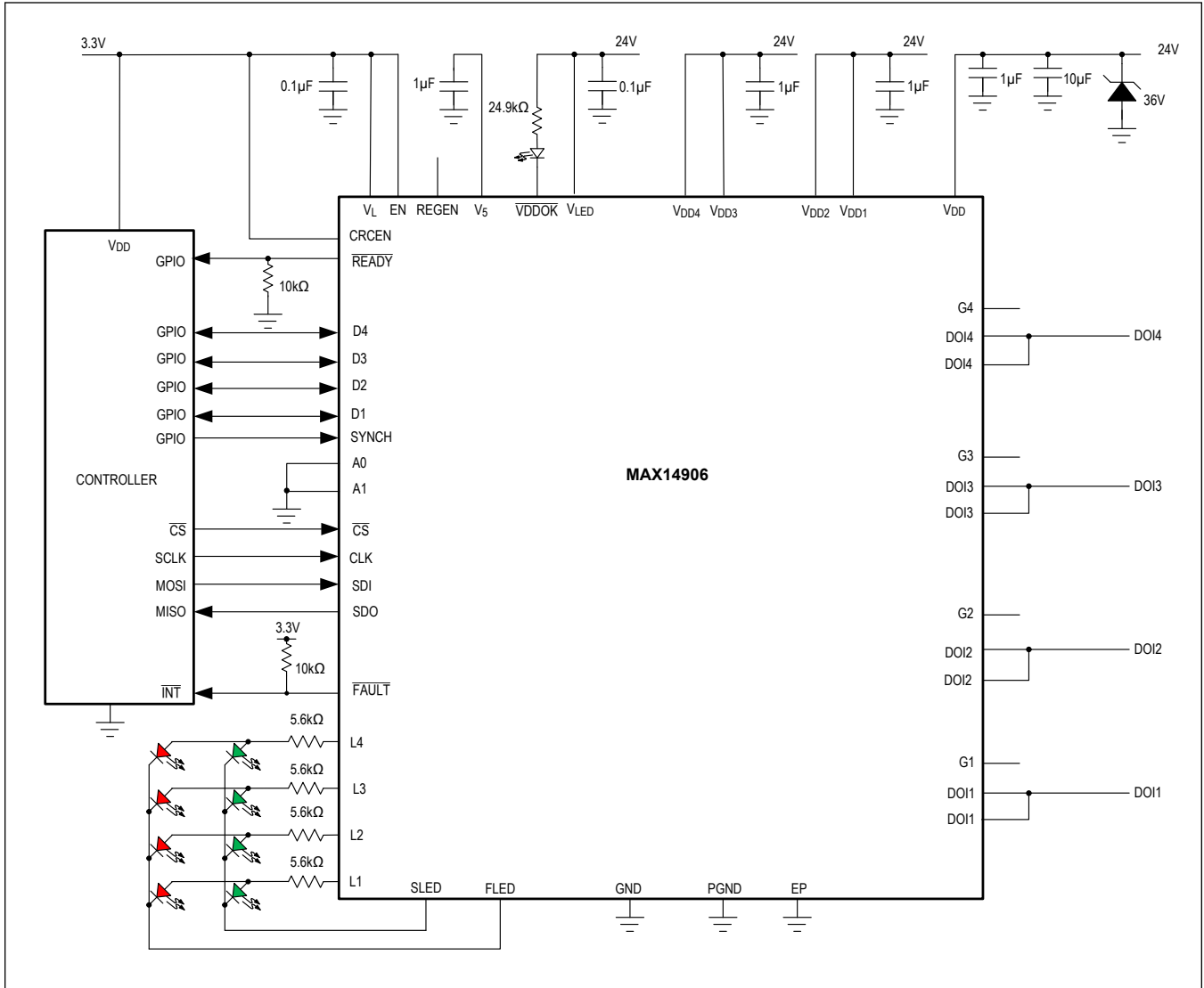
[Ordering Information](#) appears at end of datasheet.

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Quad Industrial Digital Output, Digital Input



Absolute Maximum Ratings

V_{DD}, V_{DD1}, V_{DD2}, V_{DD3}, V_{DD4}, V_{LED} -0.3V to +65V
 DOI1, DOI2, DOI3, DOI4
 V_{DD_} < V_{DD_OVTH} (V_{DD_} - 49V) to (V_{DD_} + 0.3V)
 V_{DD_} > V_{DD_OVTH} -1V to (V_{DD_} + 0.3V)
 V₅, V_L -0.3V to +6V
 SDI, CLK, CS, EN, A0, A1, SYNCH, REGEN -0.3V to +6V
 FAULT -0.3V to +6V
 D1, D2, D3, D4, SDO, $\overline{\text{READY}}$ -0.3V to (V_L + 0.3V)
 SLED, FLED, L1, L2, L3, L4, $\overline{\text{VDDOK}}$ -0.3V to (V_{LED} + 0.3V)
 G1, G2, G3, G4 -0.3V to min(40V, V_{DD_} + 0.3V)

Continuous Current
 DOI_ Load Current Internally Limited
 All Pins other than DOI_ -100mA to +100mA
 Inductive Demagnetization Energy (I_{DOI} < 0.6A) Unlimited
 Continuous Power Dissipation (T_A = +70°C)
 TQFN 48 (derate 40mW/°C above 70°C) 3200mW
 Junction Temperature Internally Limited
 Storage Temperature Range -65°C to +150°C
 Lead Temperature (soldering, 10s) +300°C
 Soldering Temperature (reflow) +260°C

Note 1: All voltages relative to GND.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

48 TQFN

| | |
|--|-------------------------|
| Package Code | T4877+6C |
| Outline Number | 21-0144 |
| Land Pattern Number | 90-0130 |
| Thermal Resistance, Four-Layer Board: | |
| Junction to Ambient (θ _{JA}) | 25°C/W |
| Junction to Case (θ _{JC}) | 1°C/W |

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Electrical Characteristics

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD_} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|--|------------------------|---|----------------------|------|------|-------|
| V_{DD} AND V_{DD_} SUPPLY VOLTAGES | | | | | | |
| Supply Voltage V _{DD} and V _{DD_} | V _{DD} | Normal Operating Conditions | 10 | | 40 | V |
| | | Overshoot Lockout Tolerance | V _{DD_OVTH} | | 65 | |
| Sum of V _{DD} and V _{DD_} Supply Currents | I _{DD_ON} | All channels in HS mode, V _{DD} = 40V, REGEN = GND, DOI_ not loaded, no load on V ₅ , gate drivers off | | 2.5 | 4.5 | mA |
| | | All channels in PP mode, V _{DD} = 40V, REGEN = GND, 10kHz switching, no load on DOI_, no load on V ₅ , gate drivers off | | 4 | 7 | |
| | | All channels in DI mode, REGEN = GND | | 2.5 | 4.5 | |
| V _{DD_} Supply Current Increase | I _{DD_ON_IN} | All G_ turned on | | 0.5 | 1.4 | mA |
| V _{DD_} Overshoot Lockout Threshold | V _{DD_OVTH} | V _{DD_} rising | 41.5 | 43.5 | 45 | V |
| V _{DD_} Overshoot Lockout Hysteresis | V _{DD_OVHYS} | | | 1 | | V |
| V _{DD} and V _{DD_} Undervoltage Lockout Threshold | V _{DD_UVLO_R} | V _{DD} , V _{DD_} rising | | | 9.6 | V |
| | V _{DD_UVLO_F} | V _{DD} , V _{DD_} falling | 7.9 | | | |
| V _{DD} and V _{DD_} Undervoltage Lockout Hysteresis | V _{DD_UVHYS} | | | 1 | | V |
| V _{DD} Undervoltage Warning Threshold | V _{DD_WARN_R} | V _{DD} rising | | | 14 | V |
| | V _{DD_WARN_F} | V _{DD} falling | 12 | | | |
| V _{DD} Undervoltage Warning Hysteresis | V _{DD_WARN_H} | | | 1 | | V |
| V _{DD} Undervoltage Good Threshold | V _{DD_GOOD_R} | V _{DD} rising | | | 17 | V |
| | V _{DD_GOOD_F} | V _{DD} falling | 15 | | | |
| V _{DD} Undervoltage Good Hysteresis | V _{DD_GOOD_H} | | | 1 | | V |
| LOGIC INTERFACE SUPPLY (V_L) | | | | | | |
| V _L Supply Voltage | V _L | | 2.5 | | 5.5 | V |
| V _L Supply Current | I _{VL} | All logic inputs high or low, logic outputs unloaded | | 18 | 40 | μA |
| V _L POR Threshold | V _{L_POR} | V _L voltage falling | 1 | 1.27 | 1.55 | V |
| 5V SUPPLY (V₅) | | | | | | |
| V ₅ Supply Voltage | V ₅ | REGEN = GND | 4.75 | 5.0 | 5.25 | V |
| V ₅ Supply Current in HS Mode | I _{V5_ON_HS} | All channels in HS mode, REGEN = GND, all DOI_ switches ON and unloaded | | 1 | 1.8 | mA |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD_} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|--|----------------------|--|------|------|------|------------|
| V_5 Supply Current in Active-Clamp PP Mode | $I_{V5_ON_PP_AC}$ | All channels in active clamp PP mode, REGEN = GND, all DOI_ switches ON and unloaded | | 1.1 | 2 | mA |
| V_5 Supply Current in Simple PP Mode | $I_{V5_ON_PP}$ | All channels in simple PP mode, REGEN = GND, all DOI_ switches ON and unloaded | | 1.1 | 2 | mA |
| V_5 Supply Current in DI Mode | $I_{V5_ON_DI}$ | All channels in DI mode, REGEN = GND, all DOI_ at 30V | | 1.1 | 2 | mA |
| V_5 Undervoltage Lockout Threshold | V_5_UVLO | V_5 rising | 3.8 | | 4.4 | V |
| V_5 Undervoltage Lockout Hysteresis | V_{5UVLO_HYS} | | | 0.3 | | V |
| 5V LINEAR REGULATOR (V_5, REGEN) | | | | | | |
| V_5 Regulator Output Voltage | V_5 | REGEN = open, 0mA to 20mA external load current | 4.75 | 5.0 | 5.25 | V |
| V_5 Regulator Current Limit | I_{CL_V5} | REGEN = open | 25 | | | mA |
| REGEN Pullup Current | I_{PU_REGEN} | REGEN = GND | 5 | | 30 | μA |
| REGEN Threshold | V_{TH_REGEN} | REGEN rising | 1 | 1.6 | 2.5 | V |
| DRIVER OUTPUTS (DOI_) | | | | | | |
| High-Side On-Resistance | R_{ON_HS} | HS or PP modes, $I_{DOI_} = 500mA$ | | 120 | 240 | m Ω |
| Low-Side On-Resistance | R_{ON_LS} | DoMode_ = 11 (Simple PP mode), $I_{DOI_} = 100mA$ | | 1 | 3 | Ω |
| Low-Side Output Low Voltage | V_{OL_LS} | Active clamp PP mode, $I_{DOI_} = 100mA$ | | | 1.2 | V |
| | | Simple PP mode, $I_{DOI_} = 100mA$ | | | 0.4 | |
| DOI_ Clamp Voltage | V_{CL} | Relative to $V_{DD_}$, $I_{DOI_} = 10mA$, $V_{DD_} < V_{DD_OVTH}$ | -63 | -55 | -49 | V |
| | | Relative to GND, $I_{DOI_} = 10mA$, $V_{DD_OVTH} < V_{DD_} < 60V$ | -6 | -4.5 | -3 | |
| DOI_ Leakage | I_{LK40_DOI} | $V_{DD_} = 40V$, HS mode, DOI_ = off, $0V < DOI_ < V_{DD_}$ | -60 | | +60 | μA |
| | I_{LKDOI_ANA} | $V_{DD_} = 40V$, low-leakage high-impedance mode, $0V < DOI_ < V_{DD_}$ | -2.4 | | +2.4 | μA |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD_} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|--|------------------------|---|-----|-----|------|-------|
| OFF STATE DIAGNOSTICS (DOI_) | | | | | | |
| Diagnostic Test Current | I _{DIAG1} | OWOffEn_ = 1, V _{DOI_} < 5V or V _{DOI_} > 9V, OWOffCs = 00, Both Open-Wire and Short-to-V _{DD} | 20 | 60 | 120 | μA |
| | I _{DIAG2} | OWOffEn_ = 1, V _{DOI_} < 5V or V _{DOI_} > 9V, OWOffCs = 01, Both Open-Wire and Short-to-V _{DD} | 60 | 100 | 180 | |
| | I _{DIAG3} | OWOffEn_ = 1, V _{DOI_} < 5V or V _{DOI_} > 9V, OWOffCs = 10, Both Open-Wire and Short-to-V _{DD} | 200 | 300 | 440 | |
| | I _{DIAG4} | OWOffEn_ = 1, V _{DOI_} < 5V or V _{DOI_} > 9V, OWOffCs = 11, Both Open-Wire and Short-to-V _{DD} | 460 | 600 | 760 | |
| DOI_ Open Voltage, OWOff_ | V _{OUT_OFF} | OWOffEn_ = 1, I _{DOI_} = 0mA | 5.8 | 6.7 | 7.6 | V |
| Open-Wire Detection Threshold, OWOff_ | V _{TH_OWOff} | OWOffEn_ = 1 | 5 | | 5.8 | V |
| Short-to-V _{DD} Detection Threshold | V _{TH_SHVDD1} | ShVddEn_ = 1, ShtVddThr = 00 | 8.2 | 9 | 10 | V |
| | V _{TH_SHVDD2} | ShVddEn_ = 1, ShtVddThr = 01 | 9.1 | 10 | 10.9 | |
| | V _{TH_SHVDD3} | ShVddEn_ = 1, ShtVddThr = 10 | 11 | 12 | 13 | |
| | V _{TH_SHVDD4} | ShVddEn_ = 1, ShtVddThr = 11 | 13 | 14 | 15 | |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS | |
|--------------------------------|--------------------|---|---|-------------------|-----|-------|----|
| CURRENT LIMITING (DOI_) | | | | | | | |
| HS Current Limit | I_{CLIM} | CL_[1:0] = 01, see Table 2 | DoMode_[1:0] = 01 and $t > t_{INRUSH}$, or DoMode_[1:0] = 00, 10 or 11 and t is don't care | 130 | 175 | 220 | mA |
| | | | DoMode_[1:0] = 01 and $t \leq t_{INRUSH}$ | 300 | 350 | 400 | |
| | | CL_[1:0] = 10, see Table 2 | DoMode_[1:0] = 01 and $t > t_{INRUSH}$, or DoMode_[1:0] = 00, 10 or 11 and t is don't care | 300 | 350 | 400 | |
| | | | DoMode_[1:0] = 01 and $t \leq t_{INRUSH}$ | 600 | 700 | 800 | |
| | | CL_[1:0] = 00, see Table 2 | DoMode_[1:0] = 01 and $t > t_{INRUSH}$, or DoMode_[1:0] = 00, 10 or 11 and t is don't care | 600 | 700 | 800 | |
| | | | DoMode_[1:0] = 01 and $t \leq t_{INRUSH}$ | 1.2 | 1.4 | 1.6 | |
| | | CL_[1:0] = 11, see Table 2 | DoMode_[1:0] = 01 and $t > t_{INRUSH}$, or DoMode_[1:0] = 00, 10 or 11 and t is don't care | 1.2 | 1.4 | 1.6 | |
| | | | DoMode_[1:0] = 01 and $t \leq t_{INRUSH}$ | 2.4 | 2.8 | 3.2 | |
| LS Current Limit | I_{CLIM_LS} | DO PP modes | 150 | 200 | 280 | mA | |
| DIGITAL INPUT (DOI_) | | | | | | | |
| Threshold Voltage | $V_{TH_DOI_DI}$ | DI mode, DOI_ rising | 6.7 | | 8.0 | V | |
| Hysteresis Voltage | $V_{HYS_DOI_DI}$ | DI mode | | 1.2 | | V | |
| Current Sink | $I_{DOI_DI_L}$ | DI mode, Typ2Di = 0, $0V < V_{DOI_} < 5V$ | 0 | | 2.6 | mA | |
| | $I_{DOI_DI_H}$ | DI mode, Typ2Di = 0, $8V < V_{DOI_} < 40V$, $V_{DOI_} < V_{DD-}$ | 2.0 | 2.3 | 2.6 | | |
| | $I_{DOI_DI_L}$ | DI mode, Typ2Di = 1, $0V < V_{DOI_} < 5V$ | 0 | | 7.5 | | |
| | $I_{DOI_DI_H}$ | DI mode, Typ2Di = 1, $8V < V_{DOI_} < 40V$, $V_{DOI_} < V_{DD-}$ | 6.0 | 7.0 | 7.7 | | |
| LOGIC INTERFACE I/O | | | | | | | |
| Input Voltage High | V_{IH} | | $0.7 \times V_L$ | | | V | |
| Input Voltage Low | V_{IL} | | | $0.3 \times V_L$ | | V | |
| Input Threshold Hysteresis | V_{IHYS} | | | $0.11 \times V_L$ | | V | |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|---|------------------|---|------------------|-----|----------------|-----------|
| Input Pull-Down Resistor | R_{IN_PD} | EN pin | 110 | 200 | 260 | $k\Omega$ |
| Input Leakage | I_{LEAK} | $GND < V_{IN} < V_L$ | -1 | | +1 | μA |
| Output Logic High | V_{OH} | $I_{LOAD} = -5mA$ | $V_L - 0.33$ | | | V |
| Output Logic Low | V_{OL} | $I_{LOAD} = +5mA$ | | | 0.33 | V |
| Output Leakage D ₋ | I_{LEAK_DOI} | DO modes | -1 | | +1 | μA |
| Output Leakage SDO | I_{LEAK_SDO} | \overline{CS} is high | -1 | | +1 | μA |
| GATE DRIVER (G₋) | | | | | | |
| V_{DD} Threshold for G ₋ Turn-on | V_{DDTH_G} | G ₋ driver clamp voltage to GND | 43 | 48 | 59 | V |
| G ₋ On Voltage | V_{ON_G} | DO modes, $DOI_{-} \leq V_{DD-}$ | $V_{DD-} - 14$ | | $V_{DD-} - 10$ | V |
| G ₋ Off Switch Resistance | R_{ON_G} | DI modes | | 50 | | Ω |
| OPEN-DRAIN OUTPUTS (\overline{FAULT}, \overline{VDDOK}, \overline{READY}) | | | | | | |
| Output Logic Low (\overline{FAULT} , \overline{VDDOK}) | V_{ODL} | $I_{LOAD} = +5mA$ | | | 0.33 | V |
| Output Logic High (\overline{READY}) | V_{ODH} | $I_{LOAD} = -5mA$ | $V_L - 0.33$ | | | V |
| Leakage (\overline{FAULT}) | I_{ODL} | Open-drain output off, $V_{OD} = 5.5V$ | -1 | | +1 | μA |
| Leakage (\overline{VDDOK}) | I_{ODL} | Open-drain output off, $V_{OD} = 40V$ | -5 | | +5 | μA |
| Leakage (\overline{READY}) | I_{ODL} | Open-drain output off, $V_{OD} = GND$ | -1 | | +1 | μA |
| LED DRIVERS (L₋, FLED, SLED) | | | | | | |
| LED Supply Voltage | V_{LED} | | 3.0 | | V_{DD} | V |
| LED Supply Current | I_{LED} | $V_{LED} = 40V$, SLED = Off, FLED = Off | | | 1 | μA |
| L ₋ Voltage High | V_{OH_L} | L ₋ = On, $I_{L-} = 5mA$ | $V_{LED} - 0.33$ | | | V |
| L ₋ Off Leakage Current | I_{LEAK_L} | L ₋ = Off, $V_{L-} = 0V$ | | | 5 | μA |
| SLED Output Voltage Low | V_{OL_SLED} | SLED = On, $I_{SLED} = 5mA$ | | | 0.33 | V |
| SLED Off Leakage Current | I_{LEAK_SLED} | SLED = Off, $V_{SLED} = V_{LED}$ | | | 5 | μA |
| FLED Output Voltage Low | V_{OL_FLED} | FLED = On, $I_{FLED} = 5mA$ | | | 0.33 | V |
| FLED Off Leakage Current | I_{LEAK_FLED} | FLED = Off, $V_{FLED} = V_{LED}$ | | | 5 | μA |
| DO MODES PROPAGATION DELAY (D₋ or SYNCH to DOI₋) | | | | | | |
| DOI Output Propagation Delay Low-to-High | t_{PD_LH} | Delay from D ₋ (or SYNCH) to DOI ₋ rising by 0.5V, HS or PP modes | | 0.4 | 1.5 | μs |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = 3.3V$, $REGEN = Open$, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|--|-------------------|---|-----|------|-----|------------|
| DOI Output Propagation Delay High-to-Low | t_{PD_HL} | Delay between D ₋ switching low (or SYNCH high) to DOI ₋ falling by 0.5V, $V_{DD} = 24V$, $R_L = 10k\Omega$, $C_L = 0.1nF$, HS or PP modes | | 0.6 | 1.5 | μs |
| DOI Output Rise Time | t_R | HS or PP modes, 20% to 80% V_{DD-} , $V_{DD-} = 24V$, $R_L = 10k\Omega$, $C_L = 0.1nF$ | | 0.6 | 1.5 | μs |
| DOI Output Fall Time | t_F | HS modes, 80% to 20% V_{DD-} , $V_{DD-} = 24V$, $R_L = 10k\Omega$, $C_L = 0.1nF$ | | 1 | | μs |
| | | PP modes, 80% to 20% V_{DD-} , $V_{DD-} = 24V$, $R_L = 10k\Omega$, $C_L = 0.1nF$ | | 0.9 | 2 | |
| DI MODES PROPAGATION DELAY (DOI₋ to D₋) | | | | | | |
| Propagation Delay High-to-Low | $t_{PD_HL_DI}$ | DI modes, SYNCH = high, delay from DOI ₋ falling to 5V to D ₋ low | | 0.9 | 1.8 | μs |
| Propagation Delay Low-to-High | $t_{PD_LH_DI}$ | DI modes, SYNCH = high, delay from DOI ₋ rising to 8V to D ₋ high | | 1.1 | 2 | μs |
| SPI TIMING CHARACTERISTICS (Figure 1) | | | | | | |
| CLK Clock Period | t_{CLK} | | 100 | | | ns |
| CLK Pulse Width High | t_{CH} | | 40 | | | ns |
| CLK Pulse Width Low | t_{CL} | | 40 | | | ns |
| \overline{CS} Fall to CLK Rise Time | t_{CSS} | | 40 | | | ns |
| SDI Hold Time | t_{DH} | | 10 | | | ns |
| SDI Setup Time | t_{DS} | | 10 | | | ns |
| SDO Propagation Delay | t_{DO} | $C_L = 10pF$, CLK falling edge to SDO stable | | | 30 | ns |
| SDO Rise and Fall Times | t_{FT} | $C_L = 10pF$ | | 1 | | ns |
| \overline{CS} Hold Time | t_{CSH} | | 40 | | | ns |
| \overline{CS} Pulse Width High | t_{CSPW} | | 40 | | | ns |
| WATCHDOG TIMING CHARACTERISTICS | | | | | | |
| Watchdog Timeout | t_{WD} | WDT ₀ = 01 | | 200 | | ms |
| | | WDT ₀ = 10 | | 600 | | |
| | | WDT ₀ = 11 | | 1200 | | |
| Watchdog Timeout Accuracy | t_{WD_ACC} | SynchWDEn = 1, see Config2 register for watchdog timeout | -30 | | +30 | % |
| LED MATRIX TIMING CHARACTERISTICS | | | | | | |
| LED Driver Scan Rate | f_{LED} | Update rate for each LED | | 1 | | kHz |
| THERMAL PROTECTION | | | | | | |
| Driver Thermal Shutdown Temperature | T_{JSHDN} | Junction temperature rising | | 170 | | $^\circ C$ |
| Driver Thermal Shutdown Hysteresis | T_{JSHDN_HYST} | | | 15 | | $^\circ C$ |

Electrical Characteristics (continued)

($V_{DD} = V_{DD1} = V_{DD2} = V_{DD3} = V_{DD4} = +10V$ to $+40V$, $V_{LED} = +3.0V$ to $+40V$, $V_5 = +4.5V$ to $+5.5V$, $V_L = +2.5V$ to $+5.5V$, $T_A = -40^\circ C$ to $+125^\circ C$, unless otherwise noted. Typical values are at $T_A = +25^\circ C$, $V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = 3.3V$, REGEN = Open, and $V_5 = 5V$.) (Note 2)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNITS |
|----------------------------------|------------------|--|-----|----------|-----|------------|
| Chip Thermal Shutdown | T_{CSHDN} | Temperature rising | | 150 | | $^\circ C$ |
| Chip Thermal Shutdown Hysteresis | T_{CSHDN_HYS} | | | 10 | | $^\circ C$ |
| LDO Thermal Shutdown | T_{LDSHDN} | | | 165 | | $^\circ C$ |
| EMC PROTECTION | | | | | | |
| ESD | V_{ESD} | DOI_ pin, IEC 61000-4-2, Contact Discharge, add a 470pF capacitor on each DOI_ to GND (Note 3) | | ± 8 | | kV |
| | | DOI_ pin, IEC 61000-4-2 Air-Gap Discharge (Note 3) | | ± 16 | | |
| | | All pins, Human Body Model | | ± 2 | | |
| Surge | V_{SURGE} | DOI_ to PGND or Earth GND, IEC 61000-4-5 (42 Ω /0.5 μF) (Note 4) | | ± 1 | | kV |

Note 2: All units are production tested at $T_A = +25^\circ C$. Specifications over temperature are guaranteed by design.

Note 3: Bypass V_{DD} and V_{DD-} pins to GND with 1 μF capacitor as close as possible to the device for high ESD protection. If an external transistor is used on V_{DD-} , place the FET as close to V_{DD-} as possible with 1 μF capacitor on the other side of the FET to PGND.

Note 4: At typical application value of $V_{DD} = 24V$ with a TVS protection on V_{DD} to GND.

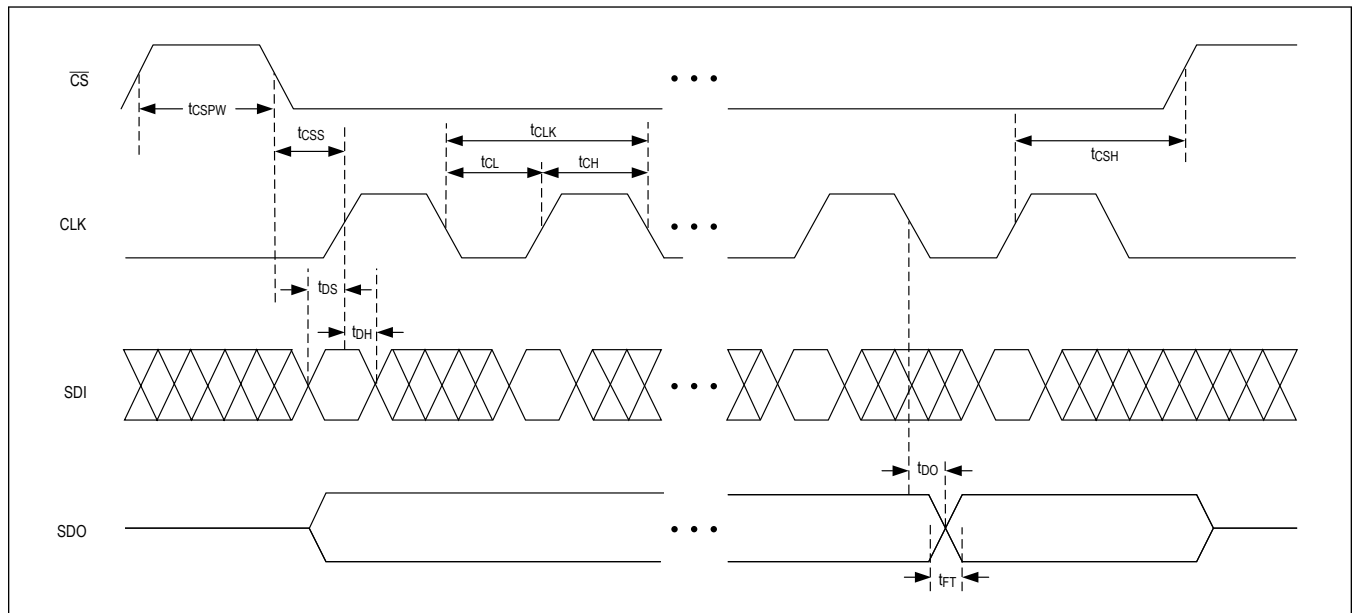
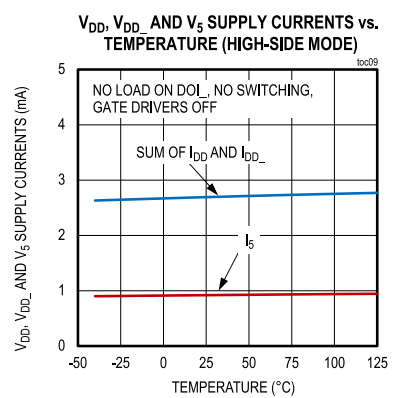
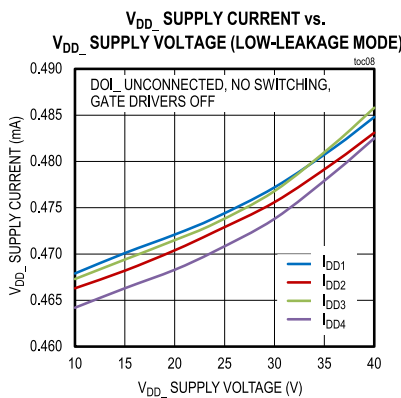
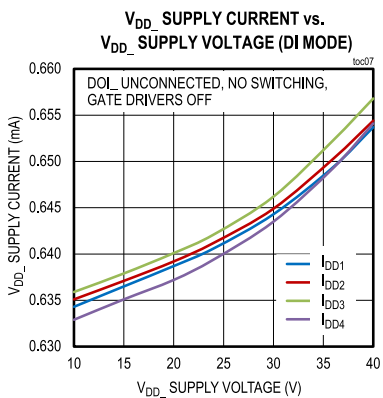
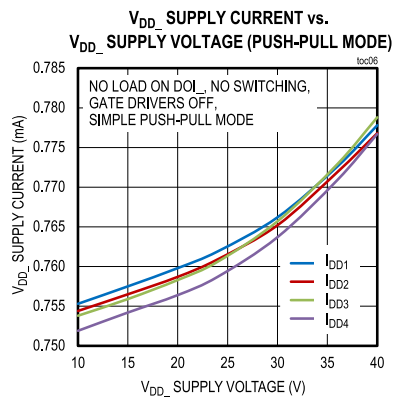
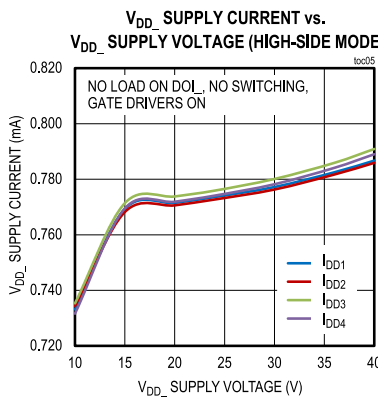
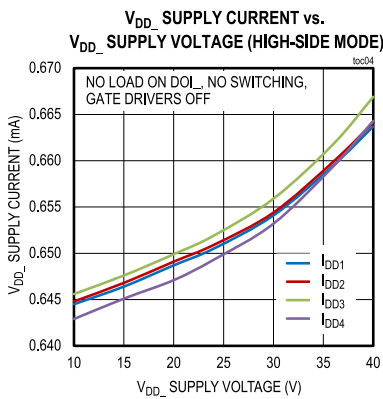
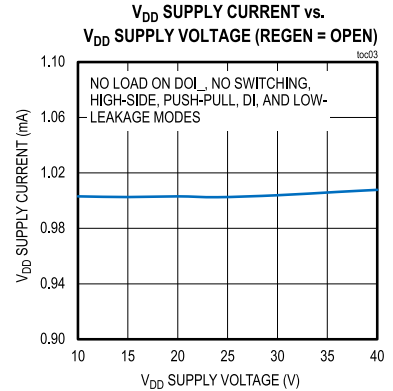
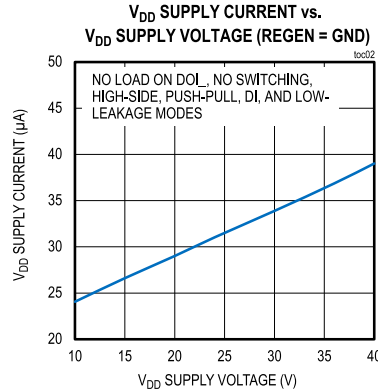
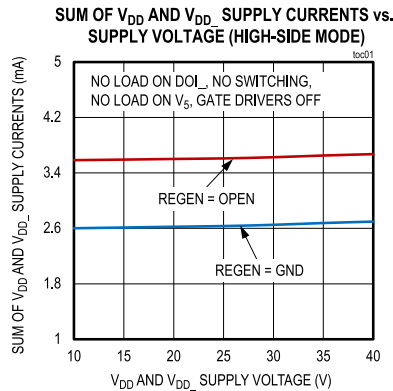


Figure 1. SPI Timing Diagram

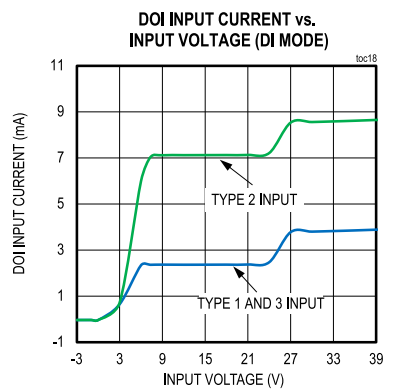
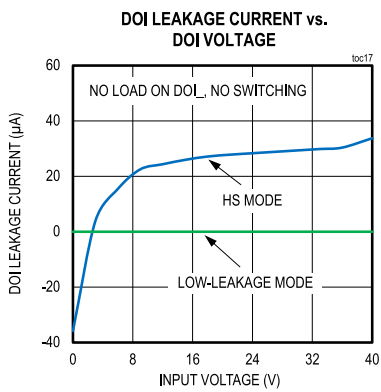
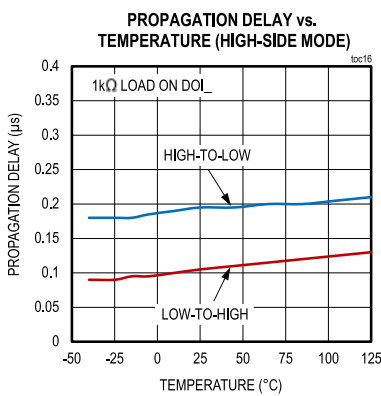
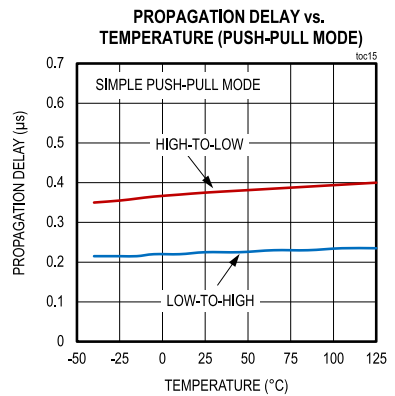
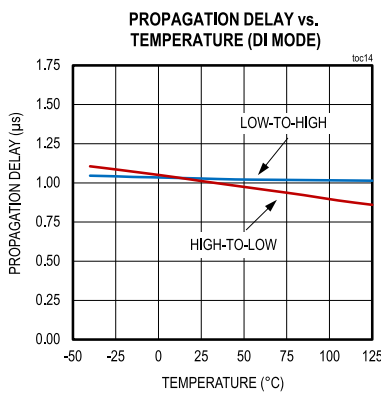
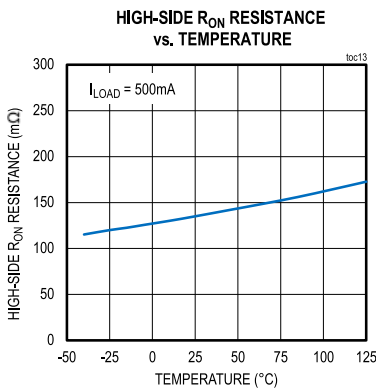
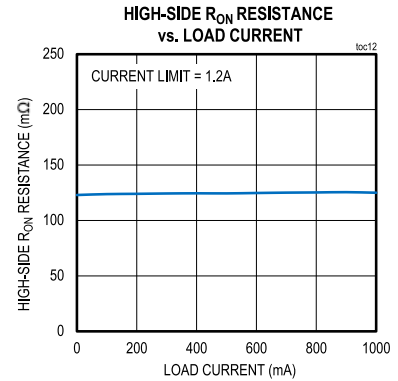
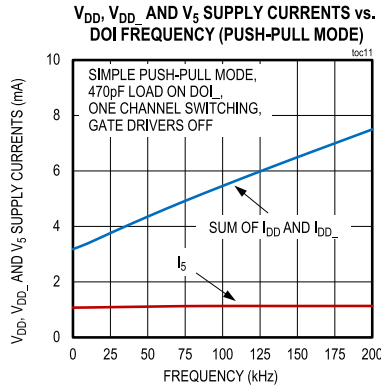
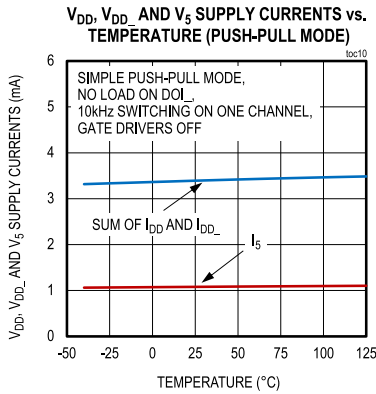
Typical Operating Characteristics

($V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = +5V$, REGEN = GND, $V_5 = +5V$, no load on V_5 , $T_A = +25^\circ C$, unless otherwise noted.)



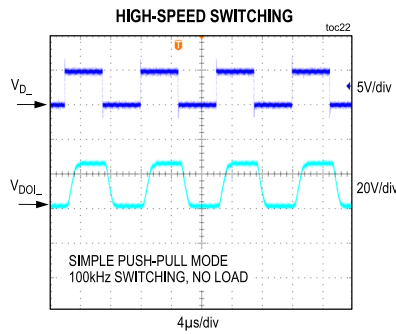
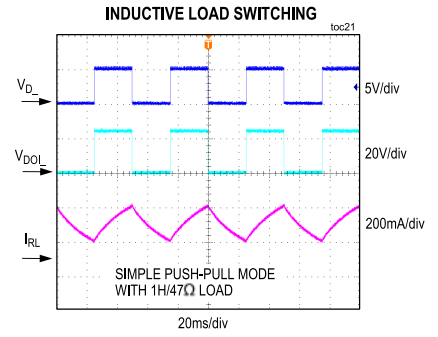
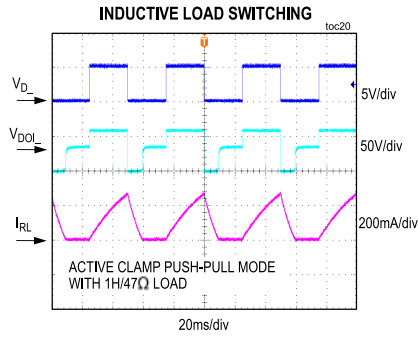
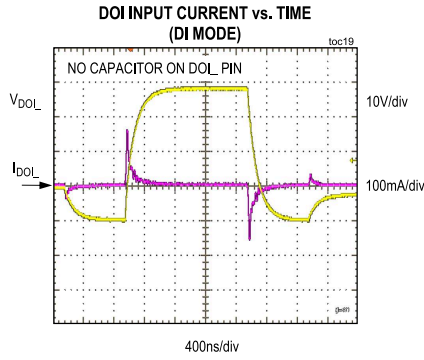
Typical Operating Characteristics (continued)

($V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = +5V$, REGEN = GND, $V_5 = +5V$, no load on V_5 , $T_A = +25^\circ C$, unless otherwise noted.)



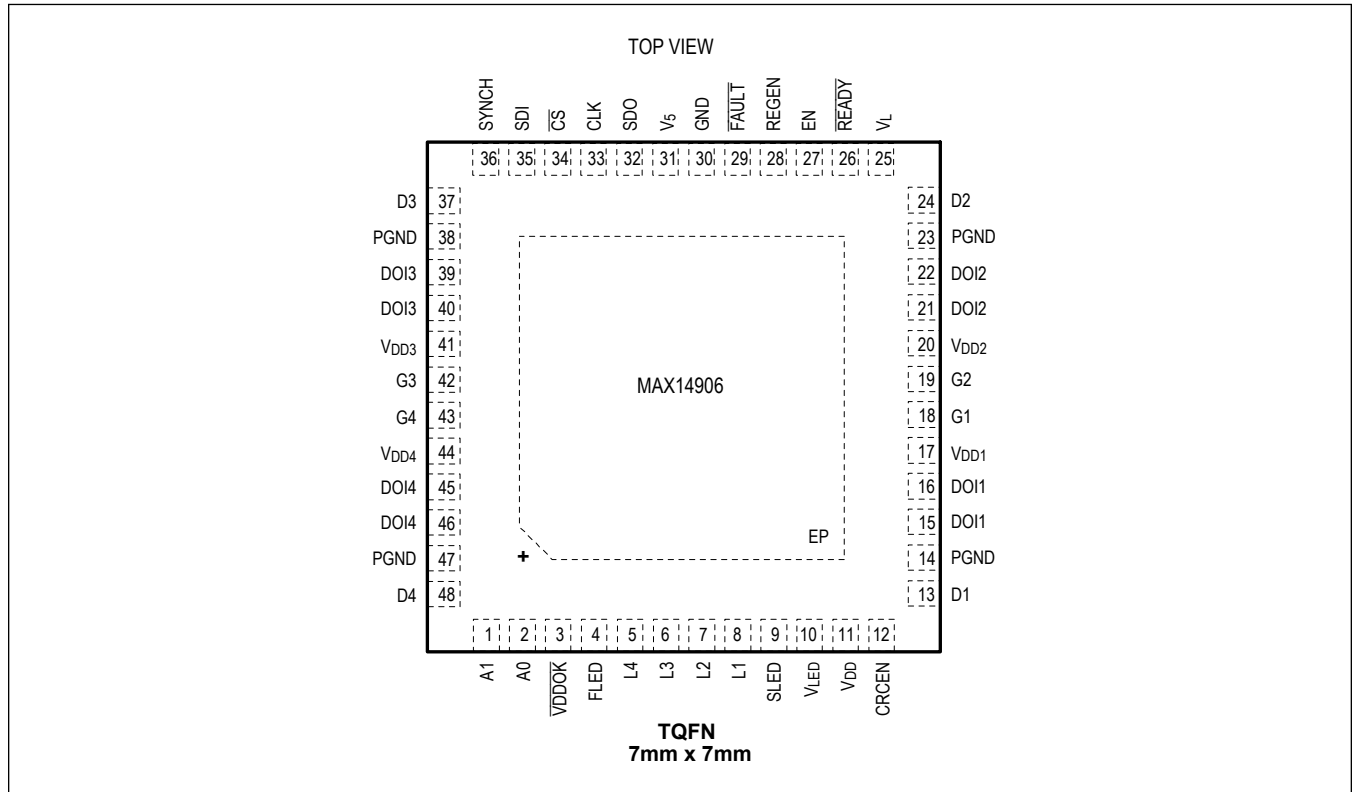
Typical Operating Characteristics (continued)

($V_{DD} = V_{DD-} = V_{LED} = +24V$, $V_L = +5V$, REGEN = GND, $V_5 = +5V$, no load on V_5 , $T_A = +25^\circ C$, unless otherwise noted.)



Pin Configuration

MAX14906



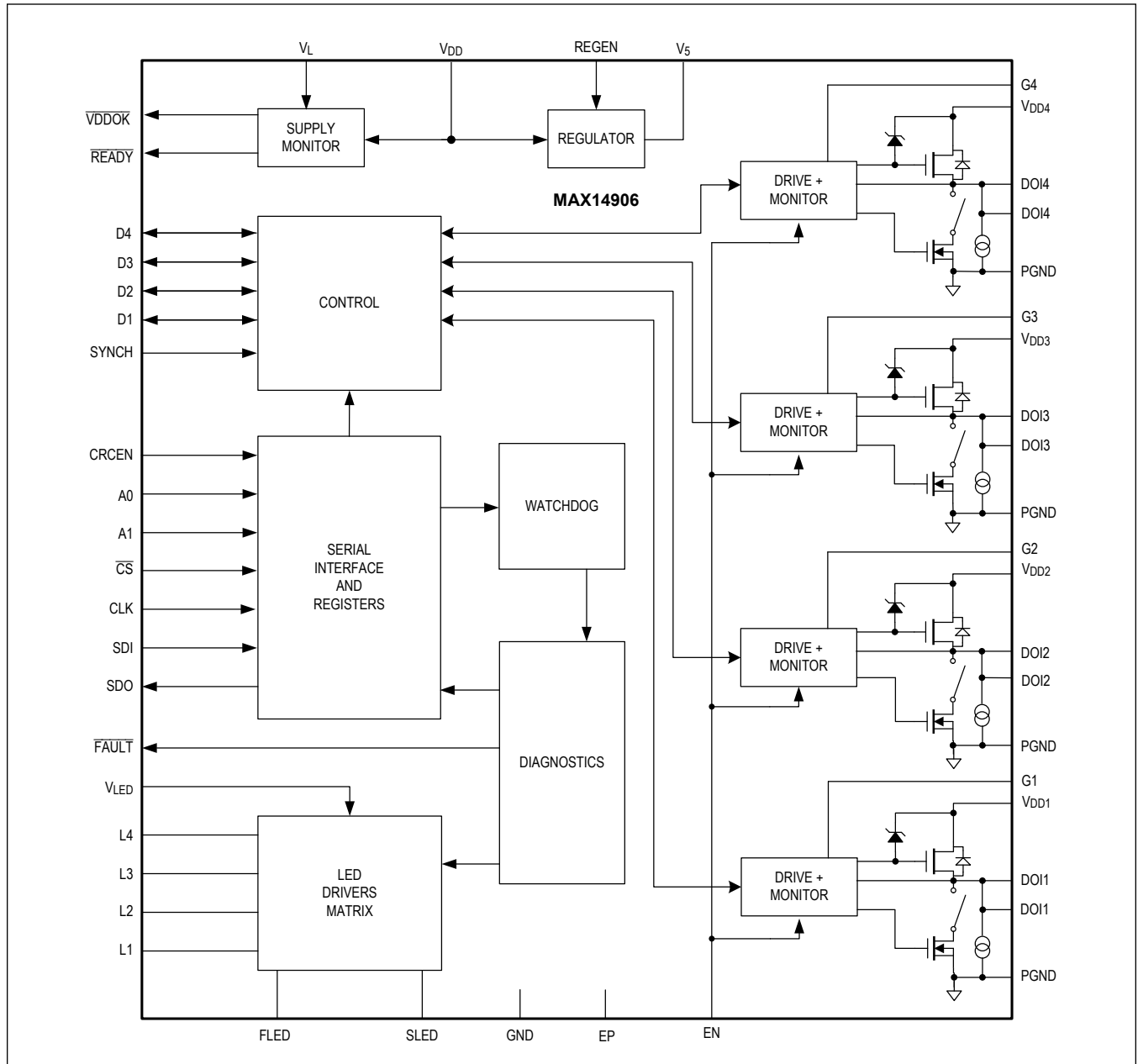
Pin Description

| PIN | NAME | FUNCTION |
|---------------------------------|--|--|
| POWER SUPPLY | | |
| 11, 17, 20, 41, 44 | V_{DD} , V_{DD1} , V_{DD2} , V_{DD3} , V_{DD4} | Supply Voltage (Nominally 24V). If using a common V_{DD} supply for all channels, connect all V_{DD} together. V_{DD} can also be independently supplied. Bypass V_{DD} to GND using a 1 μ F capacitor. Bypass the V_{DD} supplies on the same package side to GND using a shared 1 μ F capacitor. In order to allow DOI _n to go higher than V_{DD} , an optional pMOS transistor can be used on V_{DD} supply. In this case connect a 1 μ F capacitor between its drain and PGND. |
| 30 | GND | Logic/Analog Ground |
| 14, 23, 38, 47 | PGND | Power Ground. Connect all PGND pins together to GND |
| 31 | V_5 | Analog Supply Voltage/LDO Output. When REGEN is unconnected, the LDO is enabled and V_5 is a 5V supply output. If REGEN = GND, an external 5V supply has to be connected to V_5 . Bypass V_5 to GND using a 1 μ F ceramic capacitor. |
| 28 | REGEN | V_5 Regulator Enable Input. Leave REGEN unconnected for enabling/using the internal 5V regulator. Connect REGEN to GND to disable the internal regulator for powering V_5 from an external regulator. |
| 25 | V_L | Logic Reference Input. V_L defines the levels on all I/O logic interface pins. Bypass V_L to GND using a 0.1 μ F ceramic capacitor. |
| — | EP | Exposed Pad. Connect the exposed pad to GND. |
| 24V DIGITAL OUTPUT/INPUT | | |
| 15, 16 | DOI1 | Channel 1: High-Side/Push-Pull Output or Digital Input |
| 21, 22 | DOI2 | Channel 2: High-Side/Push-Pull Output or Digital Input |
| 39, 40 | DOI3 | Channel 3: High-Side/Push-Pull Output or Digital Input |
| 45, 46 | DOI4 | Channel 4: High-Side/Push-Pull Output or Digital Input |
| LOGIC INTERFACE | | |
| 13 | D1 | Logic I/O Pin. When channel 1 is in digital output mode, the D1 input switches the DOI1 output when SYNCH is high. When channel 1 is in digital input mode, the D1 output represents the logic state of the DOI1 input when SYNCH is high. |
| 24 | D2 | Logic I/O Pin. When channel 2 is in digital output mode, the D2 input switches the DOI2 output when SYNCH is high. When channel 2 is in digital input mode, the D2 output represents the logic state of the DOI2 input when SYNCH is high. |
| 37 | D3 | Logic I/O Pin. When channel 3 is in digital output mode, the D3 input switches the DOI3 output when SYNCH is high. When channel 3 is in digital input mode, the D3 output represents the logic state of the DOI3 input when SYNCH is high. |
| 48 | D4 | Logic I/O Pin. When channel 4 is in digital output mode, the D4 input switches the DOI4 output when SYNCH is high. When channel 4 is in digital input mode, the D4 output represents the logic state of the DOI4 input when SYNCH is high. |
| 36 | SYNCH | SYNCH Control Input. When DOI _n are configured as digital outputs, they are updated simultaneously on the rising SYNCH edge, as determined by the contents of the SetOUT register or the D _n input pins. The DOI _n output states do not change when SYNCH is held low. When SYNCH is high, the DOI _n output states change immediately when a new value is written into the SetOUT register or the associated D _n input pin. All DOI _n logic levels (both in DO and DI modes) are read and latched on the falling SYNCH edge. The results are stored in the DoiLevel register and the D _n output pins if the DOI _n channels are configured in DI mode. |
| 27 | EN | DOI Enable Pin. Drive the EN pin high to enable the DOI _n outputs. Drive EN low to disable/three-state all DOI _n outputs. |

Pin Description (continued)

| PIN | NAME | FUNCTION |
|--------------------------|---------------------------|---|
| 12 | CRCEN | CRC Enable Pin. Drive the CRCEN pin high to enable CRC on the SPI interface. Drive CRCEN low if CRC is not used. |
| 3 | $\overline{\text{VDDOK}}$ | Active-Low Open-Drain Logic Output. $\overline{\text{VDDOK}}$ is asserted low when the V_{DD} supply voltage is OK. Connect a pullup resistor to a voltage level between V_{L} and V_{LED} . |
| 29 | $\overline{\text{FAULT}}$ | Active-Low Open-Drain Fault Output. $\overline{\text{FAULT}}$ is asserted low when a diagnostic fault is detected on any of the channels. Connect a pullup resistor to V_{5} or V_{L} . |
| 26 | $\overline{\text{READY}}$ | High-Side Open-Drain Output. $\overline{\text{READY}}$ is passive low when the internal logic supply is higher than the UVLO threshold, indicating that the registers have adequate supply voltage. When the internal register supply falls below the UVLO threshold, the register contents are lost and $\overline{\text{READY}}$ transitions high. Connect a pulldown resistor from $\overline{\text{READY}}$ to GND. |
| 35 | SDI | Serial Data Input. SPI MOSI data input from controller. |
| 32 | SDO | Serial Data Output. SPI MISO data output to controller. |
| 33 | CLK | Serial Clock Input from Controller |
| 34 | $\overline{\text{CS}}$ | Chip Select Input from Controller |
| 2 | A0 | Chip Address LSB for Addressable SPI. See Table 7 . |
| 1 | A1 | Chip Address MSB for Addressable SPI. See Table 7 . |
| GATE DRIVERS | | |
| 18, 19, 42, 43 | G1, G2, G3, G4 | Gate Driver Outputs for Optional pMOS Transistors. Gate driver outputs are required for reverse current protection and full IEC 61131-2 Digital Input compatibility. G1 to G4 can be left unconnected when external pMOS transistors are not used. |
| LED DRIVER MATRIX | | |
| 10 | V_{LED} | Supply for LED drivers. Apply supply voltage of 3.0V to V_{DD} . |
| 9 | SLED | Status LED Cathode Connection |
| 4 | FLED | Fault LED Cathode Connection |
| 8 | L1 | Channel 1 LED Common Anode Connection. Connect a resistor in series to set the LED current. |
| 7 | L2 | Channel 2 LED Common Anode Connection. Connect a resistor in series to set the LED current. |
| 6 | L3 | Channel 3 LED Common Anode Connection. Connect a resistor in series to set the LED current. |
| 5 | L4 | Channel 4 LED Common Anode Connection. Connect a resistor in series to set the LED current. |

Functional Diagram



Detailed Description

The MAX14906 is a high-speed, four-channel IEC 61131-2-compliant industrial digital-output, digital-input device that can be configured on a per-channel basis as a high-side switch, push-pull driver, or a Type 1- and 3-, or Type 2-compliant digital input. The MAX14906 is specified for operation with a supply voltage up to 40V and is tolerant to 65V. Each channel can be supplied with an individual supply voltage that can be set at different levels.

The high-side switch current limiting is settable from 130mA to 1.2A with the option of 2x load inrush current. The high-side driver on-resistance is 120mΩ (typ) at 25°C ambient temperature. Optional push-pull operation allows high speed driving of cables and fast discharge of load capacitance. For Digital Input operation current sinks for 2.3mA (Type 1 and 3) or 7mA (Type 2) are provided.

Operating Modes

Each DOI_ channel can be individually configured for digital output operation by setting the corresponding SetDi_ bit within the SetOUT register to 0. For digital input operation, set the corresponding SetDi_ bit within the SetOUT register to 1. By default all four channels power up as outputs.

Two DoMode bits for each channel (DoMode_[1:0]) in the ConfigDO register set the output mode, high-side or push-pull, and the bit Typ2Di in the ConfigDI register controls input configuration mode, to Type 1 and 3, or Type 2. [Table 1](#) lists the options and appropriate bit settings.

For setting or reading the I/O levels, the user can use the SPI interface or directly control the four bidirectional logic pins D1 to D4.

Table 1. Operating Modes

| SetDi_ | Typ2Di | DoMode_[1:0] | MODE |
|--------|--------|--------------|---|
| 0 | X | 00 | DO Mode, High-side |
| 0 | X | 01 | DO Mode, High-side with 2x inrush current for t_{INRUSH} time |
| 0 | X | 10 | DO Mode, Active clamp push-pull |
| 0 | X | 11 | DO Mode, Simple push-pull |
| 1 | X | 1X | Low-leakage, High-impedance |
| 1 | 0 | 0X | DI Mode, Type 1 and 3 |
| 1 | 1 | 0X | DI Mode, Type 2 |

Digital Input Operation

Each channel can be configured as a Type 1 and 3, or a Type 2 digital input. However, it is not possible to mix input types as the internal current sink is globally set to either 2.3mA (typ) for Type 1 and 3, or 7mA (typ) for Type 2 inputs.

To configure a channel as an input, use the SPI interface to set the appropriate SetDi_ bit within the SetOUT register to 1. By default, inputs are configured as Type 1 and 3 with bit Typ2Di = 0 in the ConfigDI register. To change the configuration of all input channels to Type 2, set Typ2Di to 1.

To read the level of the DOI input channels, the user can poll the DoiLevel register using the SPI interface and read bits DoiLevel_/VDDOKFault_. Alternatively, the user can monitor the logic pins D1 to D4 directly.

Standard compliant digital inputs are required to support a minimal voltage range from -3V to +30V. In order to allow the DOI_ input voltage to go above the V_{DD} supply voltage and not be clamped to one diode above the field supply by the high-side body diode, an external pMOS transistor can be placed in series between the field supply and each individual V_{DD} _ supply pin, as shown in the [Typical Application Circuits](#).

Digital Output Operation

Each DOI_n channel can be configured as a high-side (HS) switch or a push-pull (PP) driver. In digital output high-side mode, the DOI_n output voltage is high when supplied from V_{DD}, and the HighO_n bit is 1 or D_n pin is high with SYNCH high. The DOI_n output is high-impedance when the HighO_n bit is 0 or D_n pin is low with SYNCH high. The high-side driver has 120mΩ (typ) on-resistance at 500mA and 25°C ambient temperature.

In digital output mode, the DOI_n output state follows the logical OR of the HighO_n bit and the D_n pin when SYNCH is high. If the application only uses the SPI interface to set DOI_n channel states, the D_n pins should be tied low with a pulldown resistor.

Except for simple push-pull mode, the DOI_n voltage can go below PGND, as occurs during inductive load demagnetization. Internal clamping structures limit the negative excursion to (V_{DD} - V_{CL}). See [Driving Inductive Loads](#) in the applications information for details. The low-side switch speeds up the discharge of RC loads in push-pull mode.

The driver output pins (DOI_n) are monitored in both high-side and push-pull modes and the corresponding logic level can be read out from the DoiLevel register, when the VDDFaultSel bit in the ConfigDI register is 0. The DOI_n threshold voltages in DO modes are the same as in DI modes. When the channels are in DO mode the DOI_n status can be read in the DoiLevel register only, but in DI mode, the DOI_n status can be read in both the DoiLevel register and from the D_n pins.

The MAX14906 has two push-pull modes. Simple push-pull mode uses a push-pull pair in which the DOI voltage switches rail-to-rail inside the V_{DD}-to-GND range even when an inductive load is present. Active-clamp push-pull mode behaves similarly to simple push-pull mode when resistive and capacitive loads are driven; however, the kick-back energy in inductive loads causes the DOI to be clamped at a negative voltage (V_{DD} - V_{CL}) when the low-side is turned on subsequent to the high-side being on. This causes fast demagnetization of inductive loads.

Reverse Current Protection and Overvoltage Support

To protect the MAX14906 against high-reverse-current flow into the DOI_n pins, an optional external pMOS transistor, as shown in the [Typical Application Circuits](#), can be used. In this case, the gate drive pins G1 to G4 must be enabled with the GDrvEn_n bits in the OpnWrEn register.

Driver Enable

When the EN pin is driven low, all DOI_n channels are disabled/three-stated, independent of the SYNCH pin level, the D_n pin levels, or the settings of the HighO_n bits in the SetOUT register.

Load Current Limiting

The maximum load currents of the high-side and low-side switches are actively limited. The current limit of the high-side switch is selectable for four operating ranges: 130mA, 300mA, 600mA, and 1.2A. Use the two CL_n bits in the CurrLim register to select the operating current range for each channel. In push-pull modes, the low-side transistor has a current limit of 150mA (min). If the high-side or low-side transistor is in active current limit, this is indicated as a current-limit fault in the CL1 to CL4 bits in the OvrLdChF register.

An overcurrent or output short-circuit generally results in a rapid temperature rise in the chip. Both the high-side and low-side transistor temperature are continuously monitored. When any channel temperature exceeds 170°C (typ), the DOI_n driver is put into high-impedance (Hi-Z) mode until the temperature falls by the hysteresis amount (15°C typ).

The result of overcurrent on both high-side and low-side switches is indicated through the current limit bits CL1 to CL4 and thermal overload is indicated through the bits OVL1 to OVL4 in the OvrLdChF register.

Inrush Current Mode

The driver inrush current mode enables 2x load current for t_{INRUSH} time. This mode allows faster turn-on of incandescent lamp loads and charging of large capacitive loads. Inrush current can be enabled per-channel using the two DoMode_ bits in the ConfigDO register, while the current limit value and inrush time (t_{INRUSH}) are set per-channel using the two CL_ bits in the CurrLim register. Refer to [Table 2](#).

Table 2. Inrush Current Mode

| CL_[1] | CL_[0] | CURRENT LIMIT (min) | INRUSH MODE CURRENT LIMIT (min) | t_{INRUSH} (ms) |
|--------|--------|---------------------|---------------------------------|--------------------------|
| 0 | 0 | 600mA | 1.2A | 20 |
| 0 | 1 | 130mA | 260mA | 50 |
| 1 | 0 | 300mA | 600mA | 40 |
| 1 | 1 | 1.2A | 2.4A | 10 |

Chip Thermal Protection

When the chip temperature rises above the thermal shutdown threshold of 150°C (typ), the chip enters thermal shutdown for protection and all DOI_ drivers are turned off until the chip temperature drops below 140°C (typ). The ThrmShutd bit in the GlobalErr register and FAULT output are set in this condition. If the chip temperature rises above 165°C, the internal LDO (V₅ regulator) goes into thermal shutdown to prevent damage to the device. In this condition, the ThrmShutd bit and FAULT output are already set. The register contents are not lost in thermal shutdown if the V_{DD} supply is present. When the chip temperature falls by the hysteresis amount, the V₅ regulator turns on, and the LED matrix and the DOI_ drivers are restored to normal operation.

Channel Thermal Management

Every channel temperature is constantly monitored. If the temperature of a channel rises above the thermal shutdown threshold of 170°C (typ), that channel is automatically turned off for protection. After the temperature drops by 15°C (typ), the driver is turned on again. When a channel turns off due to thermal shutdown, the per-channel thermal overload bit OVL_ in the OvrLdChF register and the OverLdFault bit in the Interrupt register are set to 1; the FAULT pin is asserted low if the OverLdM bit in the Mask register is set to 0.

Overvoltage Lockout

When a V_{DD} supply voltage exceeds the V_{DD_OVTH} threshold voltage of 43.5V (typ) in digital output mode for a duration longer than 200μs (typ), the high-side and low-side switches are automatically turned off. They remain turned off until V_{DD_} is reduced to below the V_{DD_OVTH} - V_{DD_OVHYST} threshold voltage.

When a V_{DD} supply voltage exceeds the V_{DD_OVTH} threshold voltage of 43.5V (typ) in digital input mode for a duration longer than 200μs (typ), the VDDOV_ bits in Sh \bar{t} VDDChF register are set and the SupplyErr bit in the Interrupt register is also set.

Power-Up and Undervoltage Lockout

When any of the V_{DD}, V₅, V_L, or V_{INT} supply voltages are under their respective UVLO thresholds, all DOI_ switches are off and the open-wire detection current sources are turned off. V_{INT} is an internally generated supply for the registers and logic circuitry derived from the V₅ or V_{DD} supply.

When the V_{DD} or V₅ supply rises, the internal logic supply V_{INT} exceeds the internal threshold (V_{TUV_INT}). If the V_L supply is also above its UVLO threshold voltage, the READY pin becomes passive-low to indicate that the part is ready for communication through the SPI interface.

After power-up, the VDD_UVLO, VDD_Low, VDD_Warn, VINT_UV and V5_UVLO bits in the GlobalErr register are set to 1, and the FAULT output is asserted low. These bits and the FAULT pin only clear once the GlobalErr register is read. The register contents are lost when the internal register supply (V_{INT}) falls below its undervoltage lockout threshold. The VINT_UV bit indicates that the register contents are in power-on-reset state and can be programmed.

When V_{DD} rises above V_{DD_UVLO_R}, in the case of VDDOnThr bit in the Config2 register set to 0, or above

$V_{DD_GOOD_R}$, in the case of $VDDOnThr$ bit set to 1, the \overline{VDDOK} pin is asserted low, indicating that the V_{DD} supply is high enough so the $DOI_switches$ can operate normally. When V_{DD} falls below $V_{DD_WARN_F}$, the VDD_Warn bit is set to 1, but the $DOI_switches$ continue operating normally. If $VddOKM$ bit in the Mask register is disabled, the $FAULT$ pin is also asserted low at the same time that the VDD_Warn bit is set to 1. When V_{DD} falls further below $V_{DD_UVLO_F}$, the VDD_UVLO bit is set and the $DOI_switches$ are turned off. The \overline{VDDOK} pin is released high when V_{DD} falls below $V_{DD_WARN_F}$, if the $VDDOnThr$ bit is set to 1. Otherwise, the \overline{VDDOK} pin is high when V_{DD} falls below $V_{DD_UVLO_F}$ if the $VDDOnThr$ bit is set to 0. The \overline{VDDOK} pin only monitors the V_{DD} supply thresholds. Refer to [Figure 2](#) and [Figure 3](#) for different V_{DD} UVLO thresholds based on different $VDDOnThr$ bit settings.

The four-channel V_{DD} supplies are also monitored. When a channel V_{DD} supply is below its threshold, as defined by the $VDDOnThr$ bit setting in the Config2 register, the per-channel $VDDOKFault_bit$ in the DoiLevel register is set if the $VDDFaultSel$ bit is set to 1 in the ConfigDI register. The $VDDOKFault_bit$ is latched and can be read and cleared through the SPI interface.

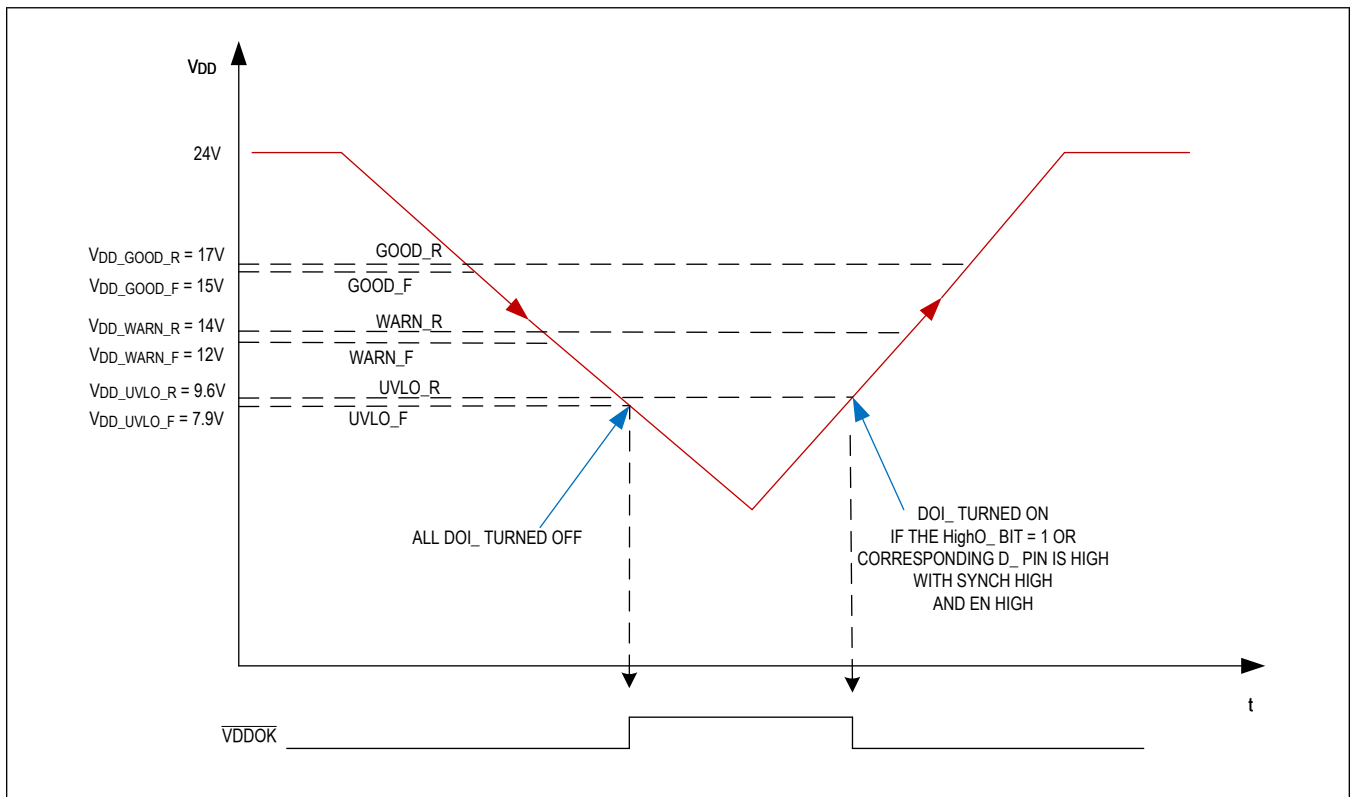


Figure 2. V_{DD} Monitoring with $VDDOnThr = 0$

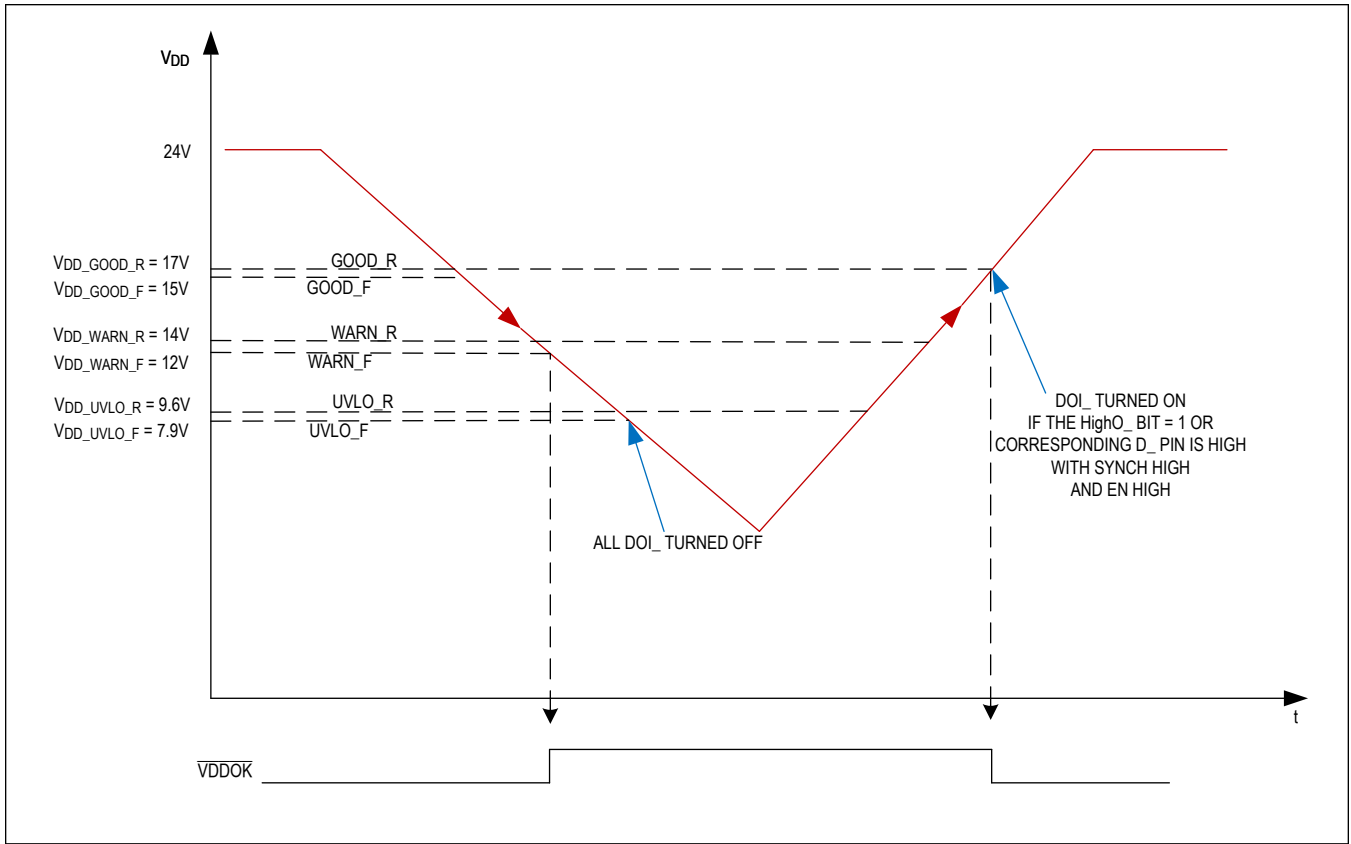


Figure 3. VDD Monitoring with VDDOnThr = 1

Diagnostics

The per-channel diagnostics are listed in [Table 3](#). These diagnostic faults are all enabled in digital output modes, and all faults are disabled (except V_{DD_OVLO} and V_{DDOK} faults) in digital input modes. [Table 4](#) summarizes the global diagnostics.

Table 3. Per-Channel Diagnostics

| PER-CHANNEL DIAGNOSTICS | ACTIVE IN HS MODE WHEN | ACTIVE IN PP MODE WHEN | ENABLED VIA | FAULT PIN INTERRUPT MASKABLE VIA |
|---------------------------------|------------------------|------------------------|--------------------|----------------------------------|
| Thermal Overload | Switch closed | Always active | Always enabled | OverLdM |
| Current Limit | Switch closed | Always active | Always enabled (*) | CurrLimM |
| Open-Wire Fault with Switch Off | Switch open | Not active | OWOffEn_ = 1 | OWOffM |
| Short-to- V_{DD} | Switch open | Not active | ShVddEn_ = 1 | ShtVddM |
| Above V_{DD} | Always active | Always active | Always enabled | AboveVDDM |
| V_{DD} OVLO (**) | Always active | Always active | VDDOVer_ = 1 | SupplyErrM |
| SafeDemag Fault | Always active | Always active | Always enabled | Not maskable |
| V_{DDOK} Fault (**) | Always active | Always active | VDDFaultSel = 1 | SupplyErrM, VDDFaultDis |

(*) Fault LEDs only signal faults according to the LEDCurrLim bit in the Config1 register.

(**) Enabled in digital input modes.

Table 4. Global Diagnostics

| GLOBAL DIAGNOSTICS | FUNCTION | FAULT PIN INTERRUPT MASKABLE VIA |
|--------------------|--|----------------------------------|
| ThrmShutd | Chip thermal shutdown | Not maskable |
| VINT_UV | Undervoltage on the internal supply for the SPI registers | SupplyErrM |
| V5_UVLO | V_5 undervoltage | SupplyErrM |
| VDD_Warn | Below V_{DD_WARN} threshold | VddOKM, SupplyErrM, VDDFaultDis |
| VDD_Low | Below V_{DD_GOOD} threshold | VddOKM, SupplyErrM, VDDFaultDis |
| VDD_UVLO | V_{DD} supply in UVLO; all DOI_ switches turned off | SupplyErrM, VDDFaultDis |
| SPI/CRC Error | CRC error, or SPI clock cycle error, or watchdog error (***) | ComErrM |
| WDogErr | SYNCH input inactivity or SPI interface inactivity | ComErrM |
| LossGND | GND is disconnected | SupplyErrM |

(***) The ComErr bit in the Interrupt register is the result of a logical OR of the SPI and SYNCH watchdog error (WDogErr), SPI number of clock cycles error, and CRC error.

Diagnostics Filtering

Open-wire detection and short-to- V_{DD} detection in conjunction with reactive loads can take many milliseconds to settle to stable conditions after a change in the high-side switch mode. During this time, diagnostic detection would not generate reliable results. After the DOI_ state switches, a blanking period of 4ms (typ) or 8ms (typ) based on the FilterLong bit in the Config1 register can be selected, during which these diagnostics are not evaluated. After this blanking time, a 4ms (typ) averaging filter is enabled after which the short-to- V_{DD} and open-wire diagnostics are updated as per-channel diagnostics in the OpnWirChF, ShtVDDChF, and the Interrupt registers. If the FLEDSet bit in the Config1 register is 0, the fault LEDs are turned on under the fault conditions, and in the next SPI cycle the diagnostic bits (SHTVDD, OWOffF) can be read from the SDO pin.

When a DOI_ switch changes state, the diagnostics for the previous state is cleared internally. The diagnostic bits in the OvrLdChF, OpnWirChF, and ShtVDDChF registers are cleared if the FLatchEn bit in the Config1 register is set to 0. If FLatchEn = 1, the diagnostic bits are cleared by a SPI read command. The faults in the GlobalErr register, SafeDemagF_ faults and VDDOKFault_ faults are always latched.

For the thermal overload and overcurrent diagnostics detection, a filter time is used (36 μ s (typ) for overload and 68 μ s (typ) for overcurrent) and there is no blanking time. To manage cold lamp loads or other heavy loads, an optional blanking time can be activated on thermal overload faults (OVL_). When DOI_ changes state, a dedicated timer masks overload faults for a period up to 300ms (typ). See the OVLBlank bits in the [ConfigDI](#) register for details. In case of cold lamp loads, per-channel thermal faults (OVL_) can blink on/off many times before reaching a steady-state, to avoid this "lamp blinking," an optional fault stretch function can be enabled to mask the thermal overload faults for a minimum 100ms (typ). See the OVLStretchEn bit in [ConfigDI](#) register for details.

AboveVDD faults are filtered with a 200 μ s (typ) debouncer with a 10.7ms (typ) stretch function after the debouncer, while V_{DD} OVLO faults (VDDOV_) is only filtered with a 200 μ s (typ) debouncer.

Open-Wire Detection with High-Side Switch Off

When an output channel is configured as a high-side switch, the MAX14906 monitors for an open-wire condition when the switch is in an off state. This can be enabled on individual channels using the OwOffEn_ bits in the OpnWrEn register. When the open-wire detection is enabled and the DOI_ switch is off, a current source is enabled, which pulls the DOI_ pins to 6.7V (typ) if there is an open-wire condition. The current source value can be set between 60 μ A (typ) to 600 μ A (typ) using OWOffCs[1:0] bits in the Config2 register.

If the DOI_ voltage is above 5V (min), an open-wire fault is indicated and the OWOff_ bits in the OpnWirChF register and the OWOffFault bit in the Interrupt register are set. The I_{DIAG} current source is turned off when open-wire detection is disabled on a channel.

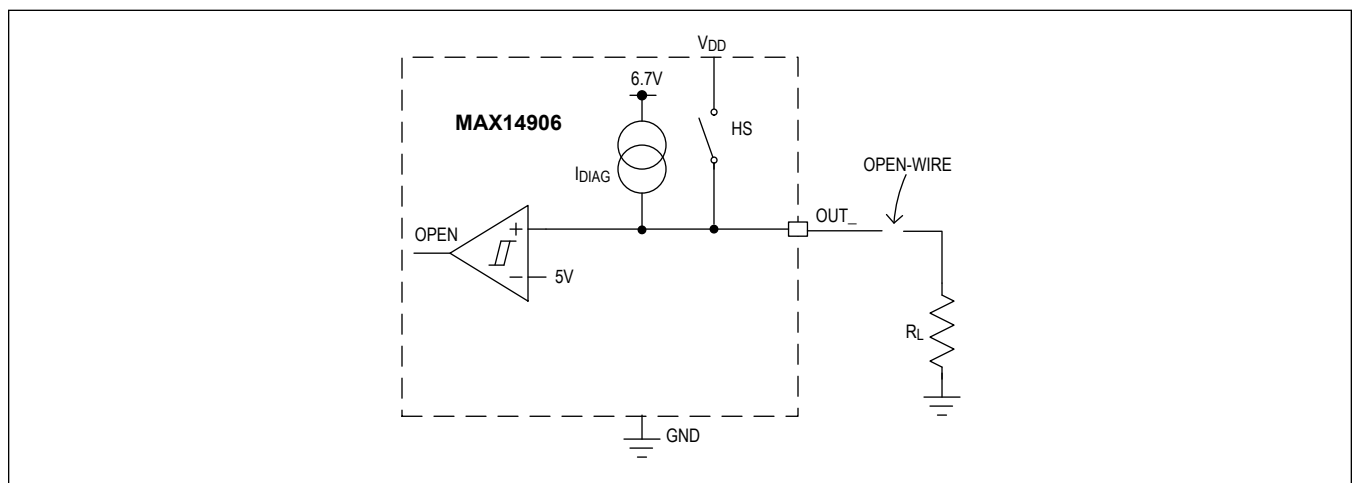


Figure 4. Open-Wire Detection with Switch OFF

Short-to- V_{DD} Detection

When an output channel is configured as a high-side switch, the MAX14906 monitors for a short-to- V_{DD} condition when the switch is in the off state. This can be enabled on individual channels using the $ShVddEn_$ bits in the $ShtVDDEn$ register. When the short-to- V_{DD} detection is enabled and the $DOI_$ switch is off, a current source is enabled, which pulls the $DOI_$ pins to 6.7V (typ). The current source value can be set between $60\mu A$ (typ) to $600\mu A$ (typ) using $OWOffCs[1:0]$ bits in the $Config2$ register. If the $DOI_$ voltage is higher than the threshold voltage selected by the $ShtVddThr[1:0]$ bits in the $Config2$ register, the $ShtVDDFault$ bit in the Interrupt register and the $SHVDD_$ bits in the $ShtVDDChF$ register are set, and the \overline{FAULT} output is asserted (if not masked).

The $ShtVddThr[1:0]$ bits select a threshold between 9V (typ) and 14V (typ) when V_{DD} is above the V_{DD_GOOD} thresholds. For V_{DD} below 16V (typ), the V_{TH_SHVDD} is always set to 9V, independent of the $ShtVddThr[1:0]$ bits.

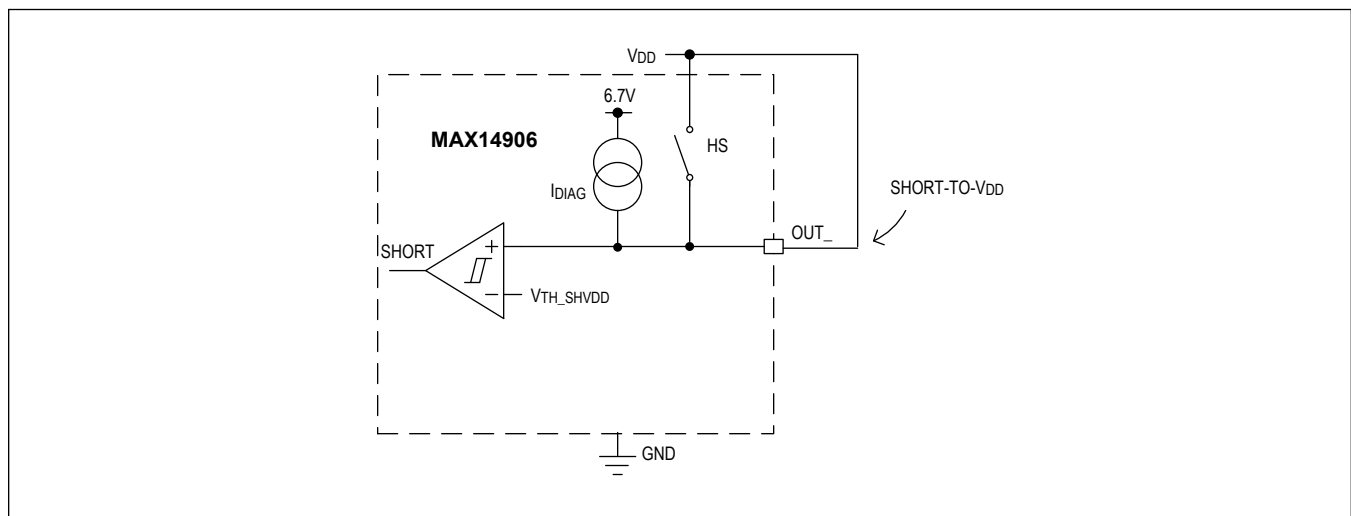


Figure 5. Short-to- V_{DD} Detection

SafeDemag Fault

The $SafeDemagF_$ bits in the $DoiLevel$ register are always latched (can never be masked), allowing the microcontroller to identify which channel went into SafeDemag condition with the resulting thermal overload of both the high-side and low-side switches.

Above- V_{DD} Fault

The MAX14906 has a comparator to monitor if the $DOI_$ outputs are higher in voltage than the V_{DD} supply. If the Above- V_{DD} condition is present after a debounce time of $200\mu s$ (typ), the $AboveVDD_$ fault bits in the $OpnWirChF$ register and the $AboveVDDFault$ bit in the Interrupt register are set.

If an external pMOS transistor is used and enabled, and the $AboveVDDProtEn$ bit in the $ConfigDI$ register is set to 1 when the $AboveVDD_$ fault is set, the external pMOS transistor is turned off for protection purposes through the $G_$ pin and the high-side switch is driven off. The $AboveVDD_$ fault is stretched for 10.7ms (typ) before the high-side switch and the external pMOS transistor are turned back on.

If an external pMOS transistor is not used, the $AboveVDD_$ faults are latched in the registers, the \overline{FAULT} pin is asserted low (if not masked), and no further action is taken on the $DOI_$ or $G_$ pins.

Loss of GND Fault

During a loss of ground event with a large inductive load, the inductor energy might be partially dissipated by the external V_{DD} TVS diode. In order to avoid stress on the TVS diode, the microcontroller or FPGA should turn the high-side switch off when the loss of ground fault is detected and indicated by the LossGND bit in the GlobalErr register. At power-on-reset, the loss of ground bit can be 1 or 0. The microcontroller should ignore this initial setting until after it reads the GlobalErr register to clear this bit for normal operation.

Watchdog Fault

The MAX14906 has two watchdog timers. One watchdog monitors activity on the SPI interface and the other monitors activity on the SYNCH pin. The SPI watchdog timer is enabled and the timeout period is set through the WDT0[1:0] bits in the Config2 register. If enabled, it monitors and expects activity on the CLK and \overline{CS} input. At least one valid SPI cycle must be detected in the watchdog timeout period. This means that the CLK input must have a multiple of 8 clock cycles during a \overline{CS} low period.

The SYNCH pin watchdog can be enabled through the SynchWDEn bit in the Config2 register if the SPI watchdog timer is disabled (WDT0[1:0] = 00). The SYNCH pin watchdog monitors if the SYNCH pin is stuck low. At least a 1 μ s (typ) SYNCH high pulse must be present in a watchdog timeout period.

If the watchdog criterion is not met, all DOI_ switches are turned off, the WDogErr bit in the GlobalErr register is set to 1, and the \overline{FAULT} pin is asserted low (if not masked).

Diagnostic Bit Behavior

The per-channel diagnostic bits (OVL_, CL_, OWOff_, AboveVDD_, SHVDD_, VDDOV_) can be configured to be latched or real-time (transparent) using the FLatchEn bit in the Config1 register. When FLatchEn = 1, the diagnostic bit is set to 1 when a fault is detected and remain as 1 even if the fault disappears. A diagnostic bit is only reset to 0 when the cause of the fault has disappeared and the relevant fault register is read. If the cause of the fault has not disappeared, the diagnostic bit remains set as 1.

The SafeDemagF_ and VDDOKFault_ bits are always latched. The fault bits in the Interrupt register (OverLdFault, CurrLim, OWOffFault, AboveVDDFault, ShtVDDFault, and DeMagFault) are the logical OR of the per-channel faults in each of the associated error registers.

FAULT Signaling

The $\overline{\text{FAULT}}$ pin is an open-drain logic output that asserts active-low when a fault condition is detected. The source of faults are the eight bits in the Interrupt register and the global thermal shutdown bit ThrmShutd in the GlobalErr register, covering per-channel faults and global faults. The source of a fault bit to assert the $\overline{\text{FAULT}}$ output can be masked using the Mask register. Refer to [Figure 6](#) for details.

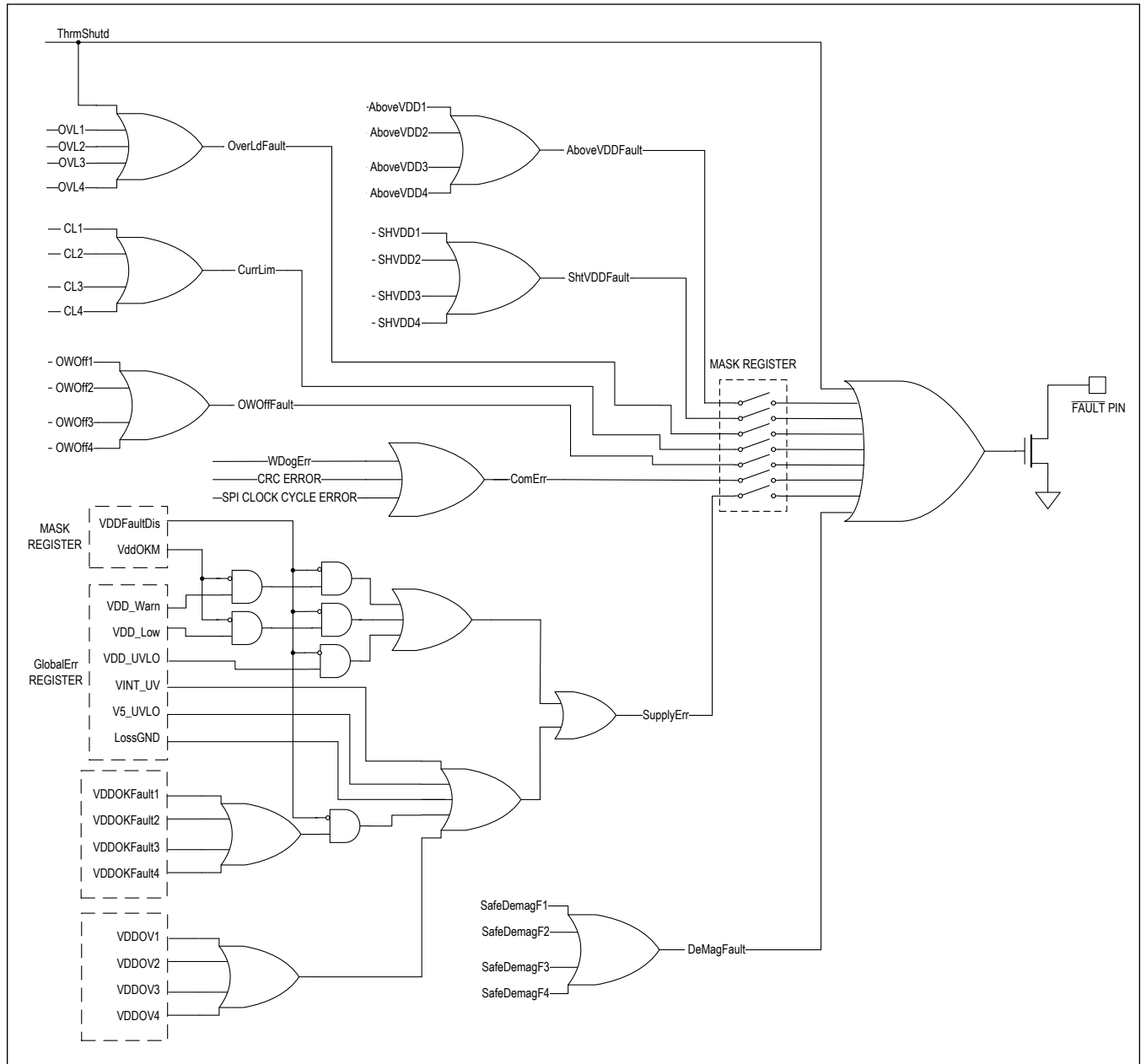


Figure 6. FAULT Interrupt Sources

Logic Interface

The logic interface features flexible logic levels, which allows the MAX14906 to interface with a wide range of logic devices such as microcontrollers or FPGAs. The V_L supply input defines the logic level and can be set in the range between 2.5V and 5.5V.

Synchronization

If SYNCH is low, the DOI_ states do not change in digital output modes, and DoiLevel_ bits and D_ pins do not change in digital input modes. If SYNCH is held high, the DOI_ switches change state immediately (transparent) when a new value is written into the SetOUT register or the D_ pins change in digital output modes. In digital input modes, the DoiLevel_ bits and D_ pins are updated as the DOI_ pins change state.

On the rising edge of SYNCH, the DOI_ channels configured as digital outputs change to a new state, which is a logical OR of the HighO_ bit in the SetOUT register and the D_ pin. On the falling edge of SYNCH, the DOI_ logic values are latched and the DoiLevel_ bits in the DoiLevel register are updated. In digital input modes, the D_ pins are also updated to represent the DOI_ levels.

Table 5. DOI_ Truth Table, Digital Input

| MODE | EN | SYNCH | DOI_ CHANNEL PINS (INPUTS) | D_ LOGIC PINS (OUTPUTS) |
|---------------|----|--------------|----------------------------|---|
| Digital Input | X | 0 | 24V Field Input | Latched, no change of state |
| | X | 1 | 24V Field Input | Logic value of DOI_, transparent |
| | X | Rising edge | 24V Field Input | Read DOI_ level and update D_ pin logic value |
| | X | Falling edge | 24V Field Input | DOI_ logic value latched |

Table 6. DOI_ Truth Table, Digital Output

| MODE | EN | SYNCH | D_ LOGIC PINS (INPUTS) | DOI_ CHANNEL PINS (OUTPUTS) |
|----------------|----|--------------|------------------------|---|
| Digital Output | 0 | X | X | Hi-Z |
| | 1 | 0 | Logic Input | No change of state |
| | 1 | 1 | Logic Input | Logical OR of HighO_ bit and D_ pin, transparent |
| | 1 | Rising edge | Logic Input | Logical OR of HighO_ bit and D_ pin, simultaneous for all DOI_ channels |
| | 1 | Falling edge | Logic Input | Latch DOI_ |

LED Matrix

The 4 x 2 LED driver crossbar matrix drives up to 8 LEDs (4 Status LEDs and 4 Fault LEDs). The LEDs can either be turned on/off by the SetLED register, or controlled by the MAX14906 autonomously to indicate per-channel status and fault conditions depending on the SLEDSet and FLEDSet bits in the Config1 register. Refer to [Figure 7](#).

If controlled autonomously (SLEDSet = 0 or FLEDSet = 0), a channel status LED (SLED) is automatically turned on when the corresponding DOI_ channel is high/on in digital output modes, or the DOI_ digital input is high in digital input modes, and there is not a diagnostic fault condition. In low-leakage high-impedance mode, the status LEDs are always off.

If a diagnostic fault condition is detected on a DOI_ channel, its associated fault LED (FLED) is turned on and its associated status LED (SLED) is automatically turned off. For any DOI_ channel, its SLED and its FLED are never on simultaneously.

When the FLEDSet bit is 0 in digital output mode, all diagnostics that are enabled (SafeDemagF_, SHVDD_, VDDOV_, OWOff_, AboveVDD_, CL_ and OVL_) result in fault LEDs turning on when a fault is detected. Only overcurrent detection can be masked (through the LEDCurrLim bit in the Config1 register) from driving the fault LEDs. If FLEDSet is 0 in digital input mode or low-leakage high-impedance mode, only Global Thermal Shutdown (the ThrmShutd bit in the GlobalErr register) drives the fault LEDs.

If the fault LEDs are controlled autonomously, they are always filtered, and the FLED minimum on-time can be programmed by the FLEDStretch[1:0] bits in the Config1 register. The status LEDs are real-time when controlled

autonomously.

The LED matrix is powered through the V_{LED} supply input, which can be in the range of the 3.0V (min) up to the V_{DD} field supply voltage.

For every current limiting resistor (R) each of the four LEDs in a column string is pulsed for 50% of the 1ms (typ) period, so that current only flows through one LED and a resistor at a time. The average current flowing through an LED that is turned on, is

$$I_{LED} = 0.5 \times (V_{LED} - V_F) / R$$

where V_F is the forward voltage of the LED. The resistor value should be chosen according to the LED current and light intensity requirements.

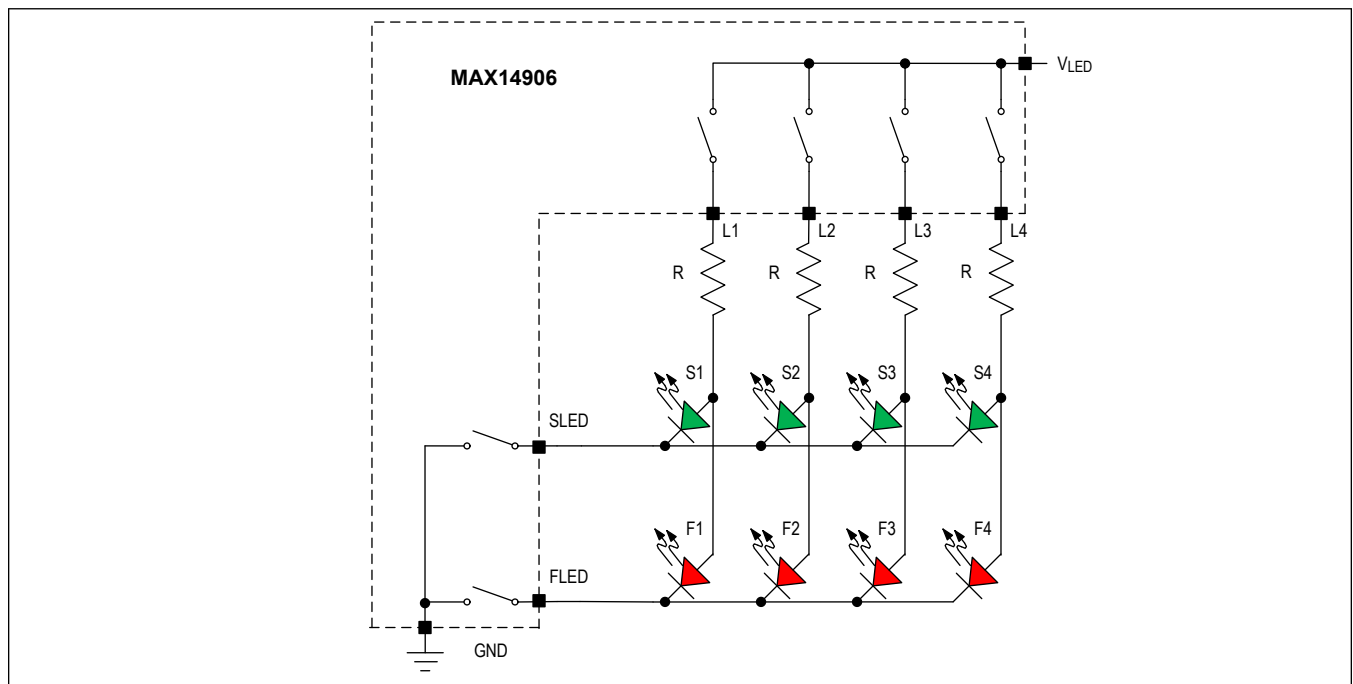


Figure 7. LED Matrix Scheme

Serial Interface

The MAX14906 has a high-speed SPI serial interface. The interface has three logic inputs: clock (CLK), chip select (\overline{CS}), serial data-in (SDI), and one output, serial data-out (SDO). The SDO is three-stated when \overline{CS} is high, allowing multiple SPI slave devices to share a common (non-daisy-chained) SPI interface. The maximum SPI clock rate is 10MHz. The SPI interface adheres with clock polarity CPOL = 0 and clock phase CPHA = 0.

The MAX14906 SPI interface supports addressable SPI, which allows direct communication with up to four MAX14906 devices on a shared SPI interface using a single \overline{CS} signal. Addressable SPI supports both single-cycle and burst read and write modes.

Addressable SPI

Each MAX14906 device on the addressable SPI interface is assigned an individual chip address through the logic input pins A1 and A0. Refer to [Table 7](#).

Table 7. SPI Device Address Selection

| A1 | A0 | DEVICE ADDRESS |
|------|------|----------------|
| LOW | LOW | 00 |
| LOW | HIGH | 01 |
| HIGH | LOW | 10 |
| HIGH | HIGH | 11 |

The SPI master addresses a specific device by sending the appropriate A1 and A0 in the first and second bits of the SPI read and write command. The MAX14906 monitors the SPI address in each SPI read and write cycle and responds with SDO appropriately when the address matches the programmed address for that IC. If CRC is enabled, the responding MAX14906 sends its A1 and A0 address bits as part of its SDO data, so the master can check that the command really reached the desired device.

SPI Diagnostic Fault Signaling

In every SPI cycle, the addressed MAX14906 returns six SDO bits within the first eight SPI CLK cycles. These six bits include the global short-to-V_{DD} (SHTVDD), Above-VDD (AbvVDD), open-wire detection in off-state (OWOffF), current limit (OvrCurr), overload (OvldF), as well as a global diagnostic bit (GLOBLF). The global fault bit (GLOBLF) is the logical OR of the ComErr, SupplyErr, and ThrmShutd bits in the Interrupt and GlobalErr registers. These six diagnostic bits allows fast identification of the specific channels in fault or global fault conditions through a minimum of further SPI read cycles.

During a SPI write cycle, the second SDO byte returns eight bits, four DoiLevel bits and four fault bits, one bit associated with each DOI_ channel. Each fault bit (F_) is the logical OR of the per-channel fault bits including SafeDemagF_, VDDOKFault_, CL_, OVL_, OWOff_, AboveVDD_, VDDOV_, and SHVDD_.

SPI Single-Cycle Write

Figure 8 shows the SPI single-cycle write command and Figure 9 shows the SPI single-cycle write command with CRC enabled.

To operate in the SPI single-cycle write mode, the BRST bit is set to 0 and the W bit is set to 1. Bits D[7:0] in the second byte sent by the controller (SDI) are the data to be written into the register selected by bits R[3:0]. The DiLv1_ and F_ bits in the second byte sent by the device (SDO) report the DOI_ channel logic levels and per-channel fault conditions. Bits F1 to F4 are the logical OR of the fault bits including SafeDemagF_, VDDOKFault_, CL_, OVL_, OWOFF_, AboveVDD_, VDDOV_, and SHVDD_. If any fault is present in any of the channels, the device immediately reports through the returned SDO data, and further SPI read commands of fault registers can be issued to identify the details.

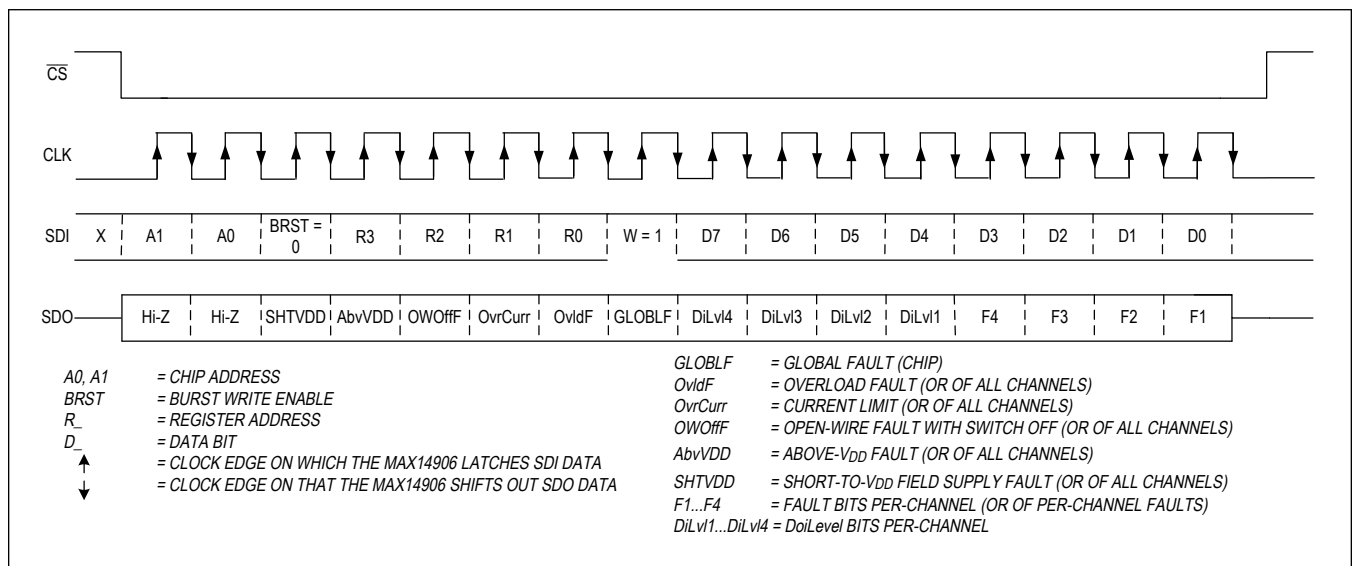


Figure 8. SPI Single-Cycle Write Command

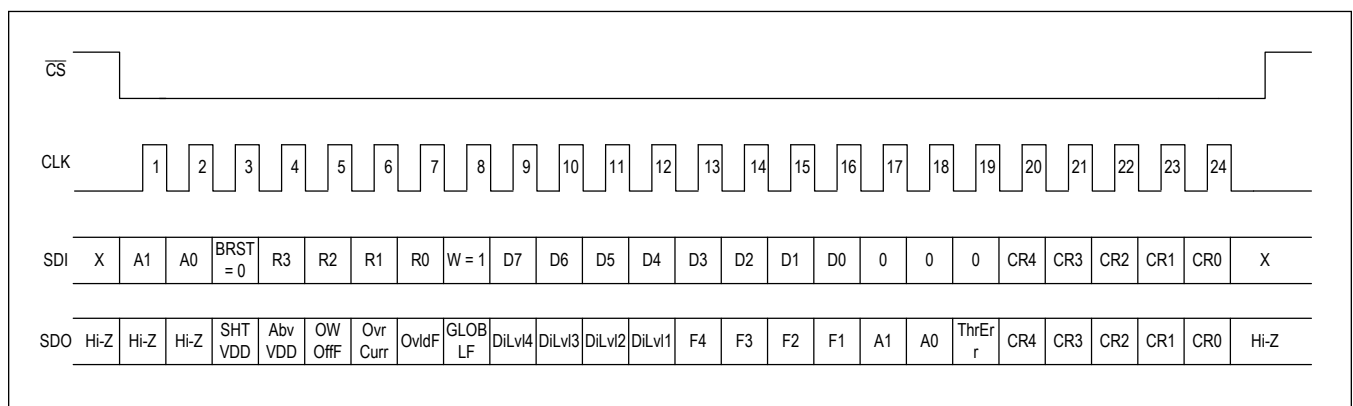


Figure 9. SPI Single-Cycle Write Command with CRC Enabled

SPI Single-Cycle Read

Figure 10 shows the SPI single-cycle read command and Figure 11 shows the SPI single-cycle read command with CRC Enabled.

To operate in the SPI single-cycle read mode, the BRST bit is set to 0 and the R bit is set to 0. Bits D[7:0] in the second byte sent by the device (SDO) are the data read from the register selected by bits R[3:0] in the first byte sent by the controller (SDI).

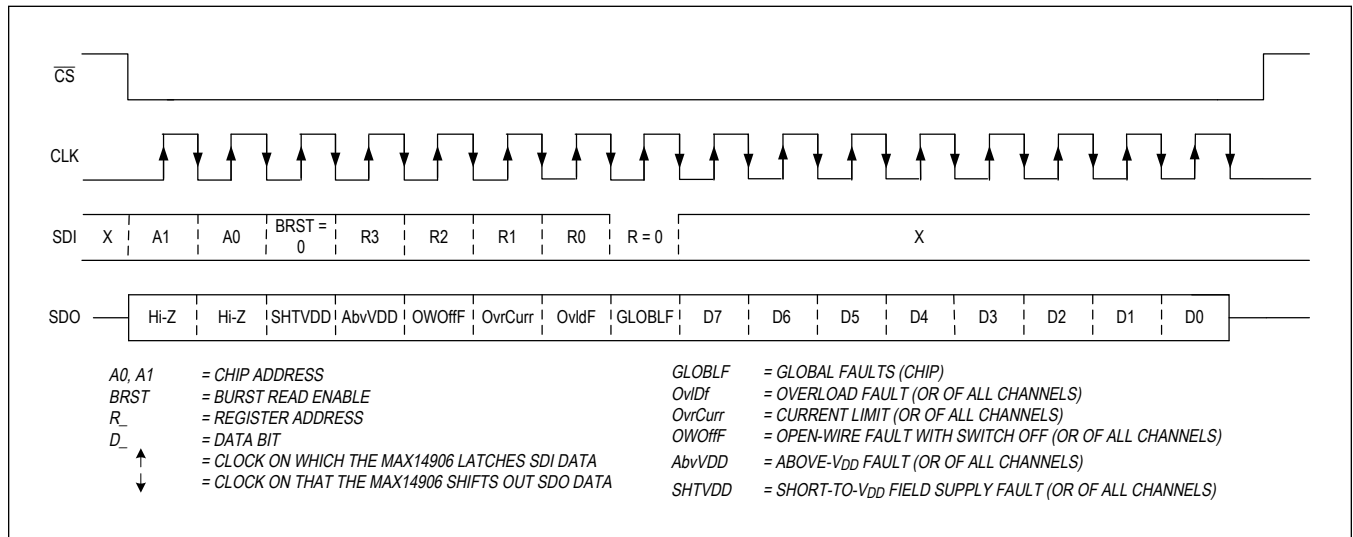


Figure 10. SPI Single-Cycle Read Command

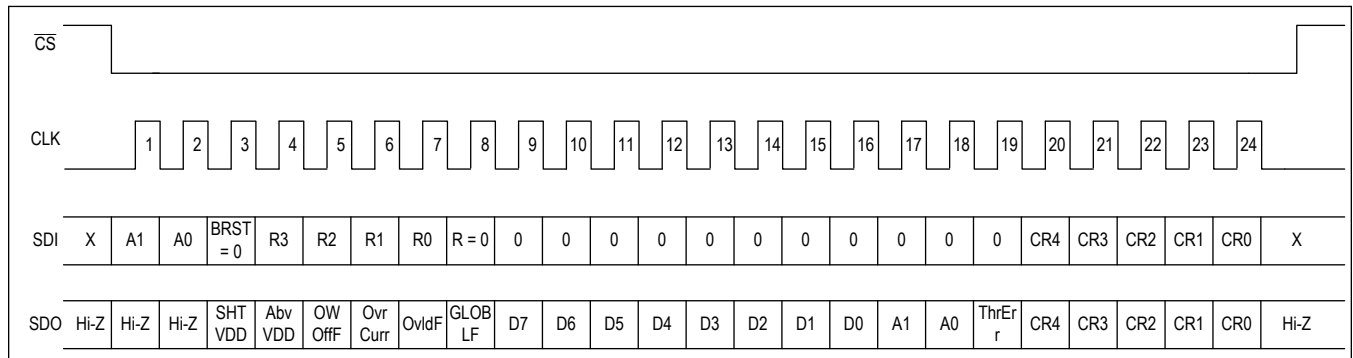


Figure 11. SPI Single-Cycle Read Command with CRC Enabled

SPI Burst Write

SPI burst mode allows using one SPI cycle and one register address to write to multiple consecutive registers and is enabled by setting the BRST bit to 1 in the SDI command byte. [Figure 12](#) and [Figure 13](#) illustrate SPI burst write diagrams. The SPI burst write command supports writing data to the most commonly accessed registers, SetOUT and SetLED.

If BRST = 1, the MAX14906 expects a SPI write cycle writing to both SetOUT and SetLED registers. The chip-select input (\overline{CS}) must be held low during the entire burst write cycle. The SPI clock continues clocking throughout the burst cycle. Only the initial register address 0x00 (SetOUT register) is specified using bits R[3:0] in the SDI command byte, followed by two bytes of data, one for the SetOUT register and the other for the SetLED register. The number of CLK cycles is 24 clock cycles if CRC is not used, and 32 clock cycles if CRC is enabled. CRC bits (CR[4:0]) are calculated on all the data sent before the CR[4:0] bits. The burst write cycle ends when the \overline{CS} is driven high.

If the burst write finishes before writing to the two registers completely or if a burst write command attempts to address other registers, a communication error is signaled on the ComErr bit in the Interrupt register.

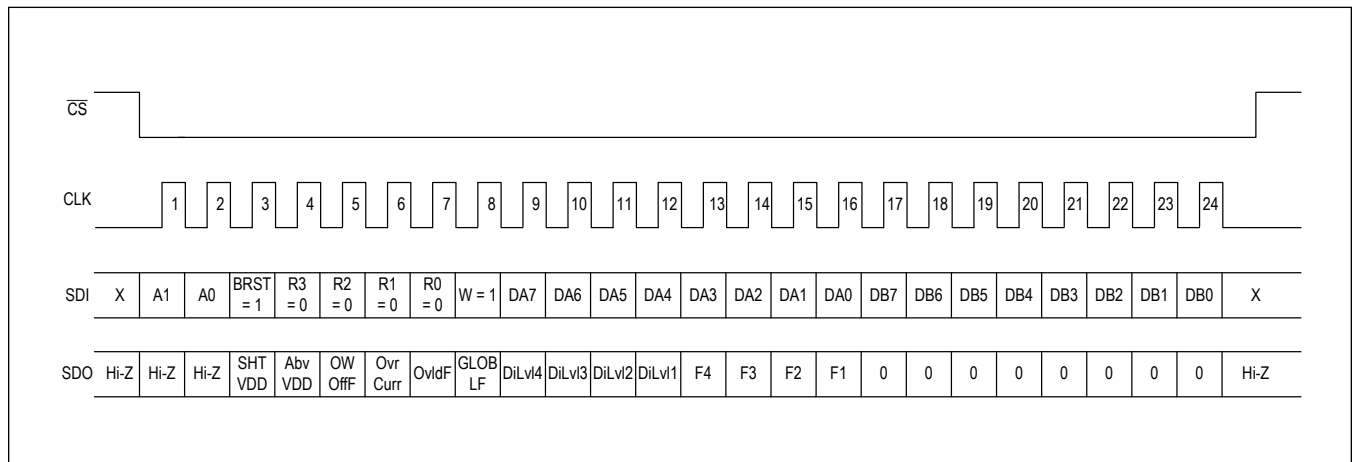


Figure 12. SPI Burst Write without CRC Enabled

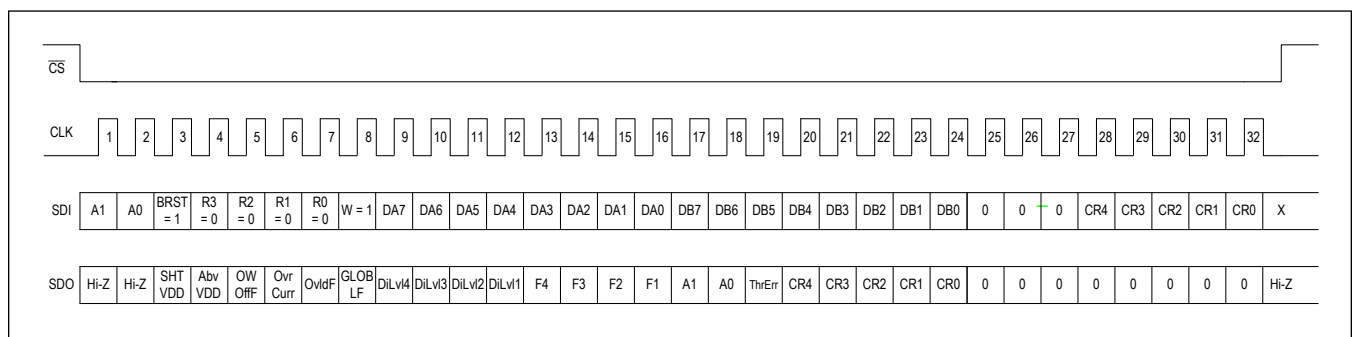


Figure 13. SPI Burst Write with CRC Enabled

SPI Burst Read

Figure 14 and Figure 15 show SPI burst read diagrams.

SPI burst mode allows using one SPI cycle and one register address to read multiple consecutive registers and is enabled by setting the BRST bit to 1 in the SDI command byte. The SPI burst read command supports reading data from the six consecutive diagnostic registers from address 0x02 to 0x07 (DoiLevel, Interrupt, OvrLdChF, OpnWirChF, ShtVDDChF, and GlobalErr registers). Note that this operation must read all six registers completely; otherwise, a communication error is flagged.

The chip-select input (\overline{CS}) must be held low during the entire burst read cycle. The SPI clock continues clocking throughout the burst cycle. The initial register address 0x02 (DoiLevel register) is specified using bits R[3:0] in the SDI command byte, and the burst read ends with register 0x07 (GlobalErr) is read. The number of CLK cycles is 56 clock cycles if CRC is not used, and 64 clock cycles if CRC is enabled. During a burst read with CRC enabled, data bits 9 to 59 in the SDI data stream can be a 0 or a 1 (they have no impact on MAX14906 configuration), but these bits are used to calculate the \overline{CRC} bits (CR[4:0]). CR[4:0] are calculated on all the data sent before the CRC bits. The burst read cycle ends when the \overline{CS} is driven high.

If the burst read command ends before the GlobalErr register has been read or if a burst read command attempts to address other registers, a communication error is signaled on the ComErr bit in the Interrupt register.

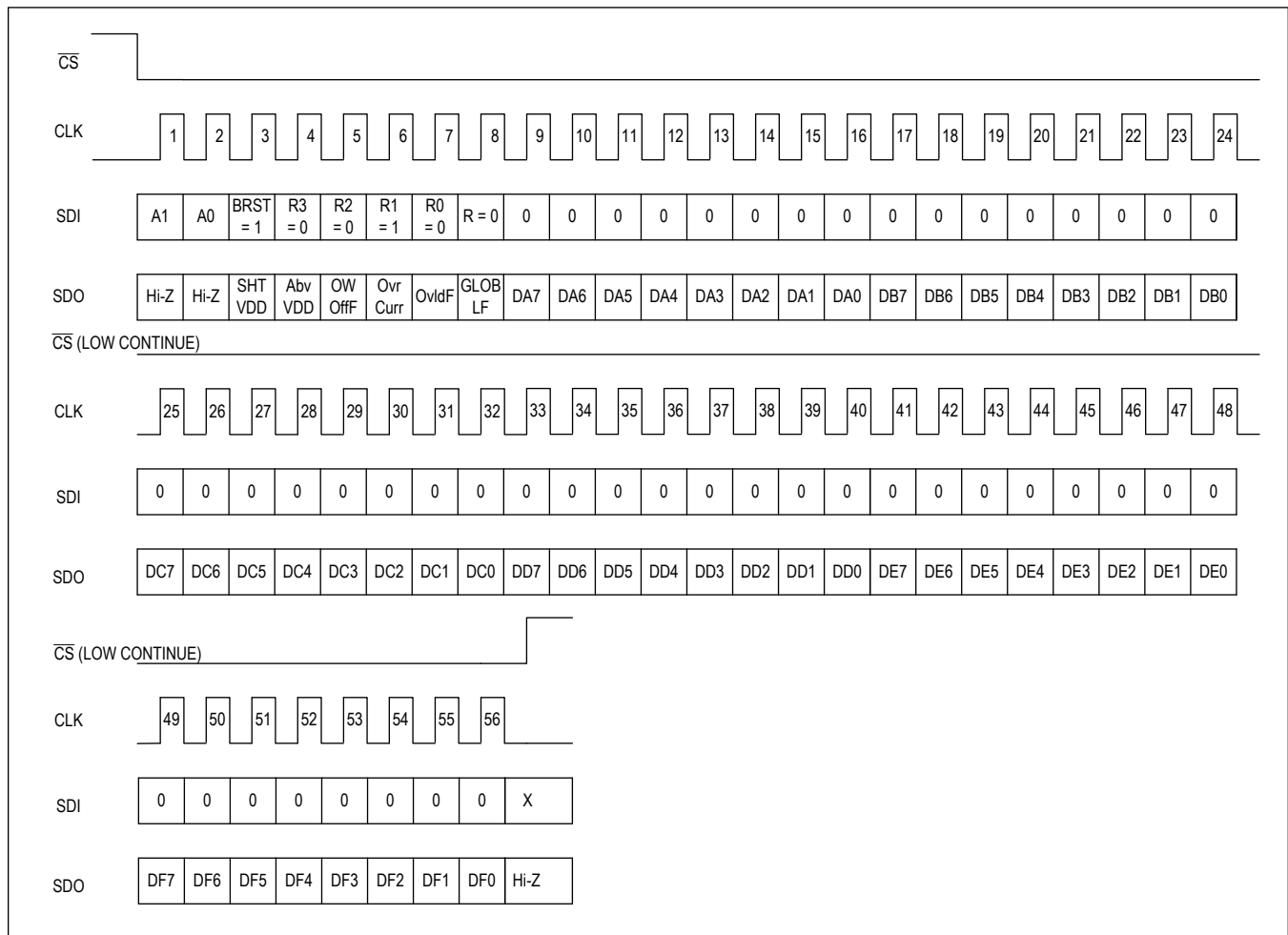


Figure 14. SPI Burst Read without CRC Enabled



Figure 15. SPI Burst Read with CRC Enabled

CRC Error Detection on the SPI Interface

CRC error detection on the SPI interface can be enabled by setting the CRCEN pin high to detect the data corruption of the SDI and SDO signals. If CRC error detection is enabled, the MAX14906:

- 1) Performs error detection on the SDI data that it receives from the controller, and
- 2) Calculates the CRC on the SDO data and appends a check byte at the end of the SDO data stream that it sends to the controller.

This ensures that both the data it receives from the controller and the data it sends to the controller maintains data integrity.

Once enabled, a CRC frame check sequence (FCS) is sent with each SPI command. The 5-bit FCS (CR[4:0]) is based on the generator polynomial $x^5 + x^4 + x^2 + 1$ with CRC starting value = 0b11111. When CRC is enabled, the MAX14906 expects a check byte appended to the SDI data stream that it receives. The check byte format (CR[4:0]) can be seen in [Figure 16](#). See [Application Note 6633](#) for more details.

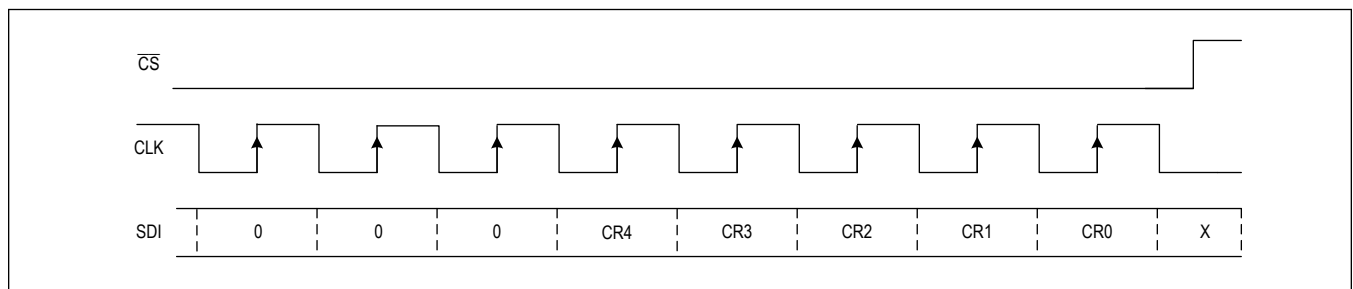


Figure 16. SDI Check Byte Expected from Controller

The 5 FCS bits in the SDI data stream are calculated on all the data bytes plus the three “0s” in the MSBs of the check byte. The CRC is calculated on 16 + 3 bits or up to 56 + 3 bits in case of a burst command. Some bits in the SDI data can be a 0 or 1 as they have no impact on the MAX14906 configuration. However, these bits are used to calculate the CRC so the microcontroller must take these bits into account when calculating the CRC, and this CRC value is appended to the end of the SDI data stream as bits CR[4:0].

The MAX14906 verifies the received FCS, and if no error is detected, the MAX14906 updates the configuration per the SDI data. If a CRC error is detected, the MAX14906 does not change the configuration, but asserts the ComErr bit in the Interrupt register.

The check byte that the MAX14906 appends to the SDO data has the format as shown in [Figure 17](#). The A1 and A0 bits identify the SPI device address of the MAX14906 that returns the SDO data. The ThrErr bit is set when a chip thermal shutdown event occurs. CR[4:0] are the CRC bits that the MAX14906 calculates based on the SDO data, including the A1, A0, and ThrErr bits. This allows the controller to check for the errors on the SDO data received from the MAX14906.

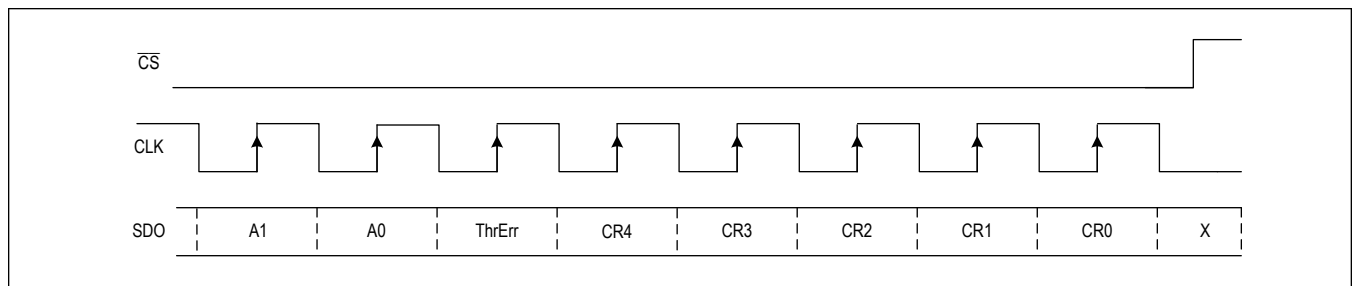


Figure 17. SDO Check Byte Sent by MAX14906

Number of Clock Cycles on the SPI Interface

The MAX14906 verifies that the number of clock cycles in one SPI cycle from the falling edge of \overline{CS} to the rising edge of \overline{CS} is a multiple of 8 with 16 clocks minimum. The expected number of clocks is scaled according to CRCEN pin configuration and burst mode setting. If the number of clock cycles differs from the expected, the SPI command is not executed and a SPI error is signaled through the ComErr bit in the Interrupt register.

Register Map

MAX14906

| ADDRESS | RESET | NAME | MSB | | | | | | | LSB |
|---------|-------|--------------------------------|--------------|-------------|--------------|-------------|---------------------------|---------------------------|---------------------------|---------------------------|
| 0x00 | 0x00 | SetOUT[7:0] | SetDi4 | SetDi3 | SetDi2 | SetDi1 | HighO4 | HighO3 | HighO2 | HighO1 |
| 0x01 | 0x00 | SetLED[7:0] | SLED4 | SLED3 | SLED2 | SLED1 | FLED4 | FLED3 | FLED2 | FLED1 |
| 0x02 | 0x00 | DoiLevel[7:0] | SafeDemagF4 | SafeDemagF3 | SafeDemagF2 | SafeDemagF1 | DoiLevel4/ VDDOKFault4 | DoiLevel3/ VDDOKFault3 | DoiLevel2/ VDDOKFault2 | DoiLevel1/ VDDOKFault1 |
| 0x03 | 0x40 | Interrupt[7:0] | ComErr | SupplyErr | DeMagFault | ShtVDDFault | AboveVDDFault | OWOffFault | CurrLim | OverLdFault |
| 0x04 | 0x00 | OvrLdChF[7:0] | CL4 | CL3 | CL2 | CL1 | OVL4 | OVL3 | OVL2 | OVL1 |
| 0x05 | 0x00 | OpnWirChF[7:0] | AboveVDD4 | AboveVDD3 | AboveVDD2 | AboveVDD1 | OWOff4 | OWOff3 | OWOff2 | OWOff1 |
| 0x06 | 0x00 | ShtVDDChF[7:0] | VDDOV4 | VDDOV3 | VDDOV2 | VDDOV1 | SHVDD4 | SHVDD3 | SHVDD2 | SHVDD1 |
| 0x07 | 0x1F | GlobalErr[7:0] | WDogErr | LossGND | ThrmShutd | VDD_UVLO | VDD_Warn | VDD_Low | V5_UVLO | VINT_UV |
| 0x08 | 0x00 | OpnWrEn[7:0] | GDrvEn4 | GDrvEn3 | GDrvEn2 | GDrvEn1 | OwOffEn4 | OwOffEn3 | OwOffEn2 | OwOffEn1 |
| 0x09 | 0x00 | ShtVDDEn[7:0] | VDDOVEn4 | VDDOVEn3 | VDDOVEn2 | VDDOVEn1 | ShVddEn4 | ShVddEn3 | ShVddEn2 | ShVddEn1 |
| 0x0A | 0x53 | Config1[7:0] | LEDCurrLim | FLatchEn | FilterLong | FFilterEn | FLEDStretch[1:0] | | SLEDSet | FLEDSet |
| 0x0B | 0x00 | Config2[7:0] | WDTto[1:0] | | OWOffCs[1:0] | | ShtVddThr[1:0] | | SynchWDEn | VDDOnThr |
| 0x0C | 0x08 | ConfigDI[7:0] | Typ2Di | Reserved | VDDFaultDis | VDDFaultSel | AboveVDDProten | OVLStretchEn | OVLBlank[1:0] | |
| 0x0D | 0x00 | ConfigDO[7:0] | DoMode4[1:0] | | DoMode3[1:0] | | DoMode2[1:0] | | DoMode1[1:0] | |
| 0x0E | 0x00 | CurrLim[7:0] | CL4[1:0] | | CL3[1:0] | | CL2[1:0] | | CL1[1:0] | |
| 0x0F | 0xBE | Mask[7:0] | ComErrM | SupplyErrM | VddOKM | ShtVddM | AboveVDDM | OWOffM | CurrLimM | OverLdM |

Register Details

[SetOUT \(0x00\)](#)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Field | SetDi4 | SetDi3 | SetDi2 | SetDi1 | HighO4 | HighO3 | HighO2 | HighO1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| SetDi4 | 7 | 0: DOI4 Digital Output Mode 1: DOI4 Digital Input Mode See the ConfigDO register for detailed configuration of digital output mode and the Typ2Di bit in the ConfigDI register for digital input mode. See Table 1 for operating mode configurations. |
| SetDi3 | 6 | 0: DOI3 Digital Output Mode 1: DOI3 Digital Input Mode |
| SetDi2 | 5 | 0: DOI2 Digital Output Mode 1: DOI2 Digital Input Mode |
| SetDi1 | 4 | 0: DOI1 Digital Output Mode 1: DOI1 Digital Input Mode |
| HighO4 | 3 | 0: DOI4 if HS mode switch = open, or PP mode driver = GND 1: DOI4 if HS mode switch = closed, or PP mode driver = V_{DD4} HighO_ is used to set the state of DOI_ when configured in DO modes. The logic state of a DOI_ output is a logical OR of the associated D_ input pin and the associated HighO_ bit. In DI modes, the associated HighO_ bit is ignored. In DO modes, the DOI_ output is high-impedance when the associated V_{DD} falls below the undervoltage-lockout threshold, but the HighO_ bit is not reset. The HighO_ bit is reset when the internal register supply voltage (V_{INT}) is below the V_{TUV_INT} threshold. |
| HighO3 | 2 | 0: DOI3 if HS mode switch = open, or PP mode driver = GND 1: DOI3 if HS mode switch = closed, or PP mode driver = V_{DD3} |
| HighO2 | 1 | 0: DOI2 if HS mode switch = open, or PP mode driver = GND 1: DOI2 if HS mode switch = closed, or PP mode driver = V_{DD2} |
| HighO1 | 0 | 0: DOI1 if HS mode switch = open, or PP mode driver = GND 1: DOI1 if HS mode switch = closed, or PP mode driver = V_{DD1} |

SetLED (0x01)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Field | SLED4 | SLED3 | SLED2 | SLED1 | FLED4 | FLED3 | FLED2 | FLED1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| SLED4 | 7 | 0: Turn off SLED4 (Status LED for DOI4) 1: Turn on SLED4 (Status LED for DOI4) The SLEDSet bit in the Config1 register determines the operating mode for this register. If SLEDSet bit = 0, status LEDs are controlled directly by the MAX14906. If SLEDSet bit = 1, status LEDs are controlled by SLED_ bits. |
| SLED3 | 6 | 0: Turn off SLED3 (Status LED for DOI3) 1: Turn on SLED3 (Status LED for DOI3) |
| SLED2 | 5 | 0: Turn off SLED2 (Status LED for DOI2) 1: Turn on SLED2 (Status LED for DOI2) |
| SLED1 | 4 | 0: Turn off SLED1 (Status LED for DOI1) 1: Turn on SLED1 (Status LED for DOI1) |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| FLED4 | 3 | 0: Turn off FLED4 (Fault LED for DOI4) 1: Turn on FLED4 (Fault LED for DOI4) The FLEDSet bit in the Config1 register determines the operating mode for this register. If FLEDSet bit = 0, fault LEDs are controlled directly by the MAX14906. If FLEDSet bit = 1, fault LEDs are controlled by FLED_ bits. |
| FLED3 | 2 | 0: Turn off FLED3 (Fault LED for DOI3) 1: Turn on FLED3 (Fault LED for DOI3) |
| FLED2 | 1 | 0: Turn off FLED2 (Fault LED for DOI2) 1: Turn on FLED2 (Fault LED for DOI2) |
| FLED1 | 0 | 0: Turn off FLED1 (Fault LED for DOI1) 1: Turn on FLED1 (Fault LED for DOI1) |

DoiLevel (0x02)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|--------------------|--------------------|--------------------|--------------------|---------------------------|---------------------------|---------------------------|---------------------------|
| Field | SafeDemag F4 | SafeDemag F3 | SafeDemag F2 | SafeDemag F1 | DoiLevel4/ VDDOKFault4 | DoiLevel3/ VDDOKFault3 | DoiLevel2/ VDDOKFault2 | DoiLevel1/ VDDOKFault1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION |
|---------------------------|------|---|
| SafeDemagF4 | 7 | 0: Normal operating conditions 1: Thermal Overload on DOI4 during SafeDemag. This fault is always latched and never masked. |
| SafeDemagF3 | 6 | 0: Normal operating conditions 1: Thermal Overload on DOI3 during SafeDemag. This fault is always latched and never masked. |
| SafeDemagF2 | 5 | 0: Normal operating conditions 1: Thermal Overload on DOI2 during SafeDemag. This fault is always latched and never masked. |
| SafeDemagF1 | 4 | 0: Normal operating conditions 1: Thermal Overload on DOI1 during SafeDemag. This fault is always latched and never masked. |
| DoiLevel4/ VDDOKFault4 | 3 | Functionality controlled by the VDDFaultSel bit in the ConfigDI register: If VDDFaultSel = 0, reports DOI4 logic level in DI and DO modes. If VDDFaultSel = 1, reports a VDDOK bit fault for the V _{DD4} supply. VDDOKFault_ bits are set when per-channel VDDOK condition is not met (V _{DD} thresholds are controlled by the VDDOnThr bit in the Config2 register). This fault is always latched. VDDOKFault_ bits affect the SupplyErr fault bit in the Interrupt register if the VDDFaultDis bit in the ConfigDI register is not set. It also asserts the FAULT pin if not masked by the SupplyErrM bit in the Mask register. |
| DoiLevel3/ VDDOKFault3 | 2 | If VDDFaultSel = 0, reports DOI3 logic level in DI and DO modes. If VDDFaultSel = 1, reports a VDDOK bit fault for the V _{DD3} supply. |
| DoiLevel2/ VDDOKFault2 | 1 | If VDDFaultSel = 0, reports DOI2 logic level in DI and DO modes. If VDDFaultSel = 1, reports a VDDOK bit fault for the V _{DD2} supply. |
| DoiLevel1/ VDDOKFault1 | 0 | If VDDFaultSel = 0, reports DOI1 logic level in DI and DO modes. If VDDFaultSel = 1, reports a VDDOK bit fault for the V _{DD1} supply. |

[Interrupt \(0x03\)](#)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-----------|-----------|------------|-------------|----------------|------------|-----------|-------------|
| Field | ComErr | SupplyErr | DeMagFault | ShtVDDFault | AboveVDD Fault | OWOffFault | CurrLim | OverLdFault |
| Reset | 0b0 | 0b1 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0x0 |
| Access Type | Read Only | Read Only | Read Only | Read Only | Read Only | Read Only | Read Only | Read Only |

| BITFIELD | BITS | DESCRIPTION |
|---------------|------|---|
| ComErr | 7 | 0: Normal operating conditions 1: Communication error detected ComErr is the logic OR result of an SPI watchdog error (if enabled), a SYNCH watchdog error (if enabled), an SPI CRC error (if enabled), and a number of SPI clock cycles error. |
| SupplyErr | 6 | 0: Normal operating conditions 1: Supply error detected SupplyErr is the logical OR result of VDDOV_bits, VDDOKFault_faults (if enabled by the VDDFaultDis bit in the ConfigDI register), and the 6 supply error bits (VDD_UVLO, VDD_Warn, VDD_Low, V5_UVLO, VINT_UV, and LossGND) in the GlobalErr register. |
| DeMagFault | 5 | 0: Normal operating conditions 1: SafeDemag fault detected on any DOI channel Logic OR result of per-channel SafeDemag faults. The per-channel faults can be identified using the SafeDemagF_bits in the DoiLevel register. |
| ShtVDDFault | 4 | 0: Normal operating conditions 1: Short-to-V _{DD} fault detected on any DOI channel Logic OR result of per-channel short-to-V _{DD} faults. The per-channel faults can be identified using SHVDD_bits in the ShtVDDChF register. |
| AboveVDDFault | 3 | 0: Normal operating conditions 1: Above-V _{DD} fault detected on any DOI channel Logic OR result of per-channel above-V _{DD} faults. The per-channel faults can be identified using the AboveVDD_bits in the OpnWirChF register. |
| OWOffFault | 2 | 0: Normal operating conditions 1: Open-wire fault in off state detected on any DOI channel Logic OR result of per-channel open-wire faults. The per-channel faults can be identified using the OWOff_bits in the OpnWirChF register. |
| CurrLim | 1 | 0: Normal operating conditions 1: Overcurrent occurred on any DOI channel Logic OR result of per-channel current limit faults. The per-channel faults can be identified using the CL_bits in the OvrLdChF register. |
| OverLdFault | 0 | 0: Normal operating conditions 1: Thermal overload occurred on any DOI channel Logic OR result of per-channel thermal overload faults and the global thermal shutdown bit ThrmShutd. The per-channel faults can be identified using the OVL_bits in the OvrLdChF register. |

[OvrLdChF \(0x04\)](#)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| Field | CL4 | CL3 | CL2 | CL1 | OVL4 | OVL3 | OVL2 | OVL1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|---|
| CL4 | 7 | 0: Normal operating conditions 1: Current limit detected on DOI4 The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when OvrLdChF register is read AND a current limiting condition is not present. |
| CL3 | 6 | 0: Normal operating conditions 1: Current limit detected on DOI3 |
| CL2 | 5 | 0: Normal operating conditions 1: Current limit detected on DOI2 |
| CL1 | 4 | 0: Normal operating conditions 1: Current limit detected on DOI1 |
| OVL4 | 3 | 0: Normal operating conditions 1: Thermal overload is detected on DOI4 The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when the OvrLdChF register is read AND a thermal overload condition is not present. |
| OVL3 | 2 | 0: Normal operating conditions 1: Thermal overload is detected on DOI3 |
| OVL2 | 1 | 0: Normal operating conditions 1: Thermal overload is detected on DOI2 |
| OVL1 | 0 | 0: Normal operating conditions 1: Thermal overload is detected on DOI1 |

[OpnWirChF \(0x05\)](#)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| Field | AboveVDD4 | AboveVDD3 | AboveVDD2 | AboveVDD1 | OwOff4 | OwOff3 | OwOff2 | OwOff1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION |
|-----------|------|--|
| AboveVDD4 | 7 | 0: Normal operating conditions 1: Above-V _{DD} fault is detected on DOI4 The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when OpnWirChF register is read AND the fault condition is not present. The Above-V _{DD} fault is always stretched by 10.7ms (typ), so once it is detected it is set for at least 10.7ms (typ). |

| BITFIELD | BITS | DESCRIPTION |
|-----------|------|--|
| AboveVDD3 | 6 | 0: Normal operating conditions 1: Above- V_{DD} fault is detected on DOI3 |
| AboveVDD2 | 5 | 0: Normal operating conditions 1: Above- V_{DD} fault is detected on DOI2 |
| AboveVDD1 | 4 | 0: Normal operating conditions 1: Above- V_{DD} fault is detected on DOI1 |
| OwOff4 | 3 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Open-wire fault is detected on DOI4 when the high-side switch is in the off state The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when the OpnWirChF register is read AND the fault condition is not present. |
| OwOff3 | 2 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Open-wire fault is detected on DOI3 when the high-side switch is in the off state |
| OwOff2 | 1 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Open-wire fault is detected on DOI2 when the high-side switch is in the off state |
| OwOff1 | 0 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Open-wire fault is detected on DOI1 when the high-side switch is in the off state |

ShtVDDChF (0x06)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| Field | VDDOV4 | VDDOV3 | VDDOV2 | VDDOV1 | SHVDD4 | SHVDD3 | SHVDD2 | SHVDD1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| VDDOV4 | 7 | 0: Normal operating conditions 1: V_{DD4} supply is higher than the V_{DD_OVTH} threshold voltage (43.5V, typ) The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when ShtVDDChF register is read AND the fault condition is not present. |
| VDDOV3 | 6 | 0: Normal operating conditions 1: V_{DD3} supply is higher than the V_{DD_OVTH} threshold voltage (43.5V, typ) |
| VDDOV2 | 5 | 0: Normal operating conditions 1: V_{DD2} supply is higher than the V_{DD_OVTH} threshold voltage (43.5V, typ) |
| VDDOV1 | 4 | 0: Normal operating conditions 1: V_{DD1} supply is higher than the V_{DD_OVTH} threshold voltage (43.5V, typ) |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| SHVDD4 | 3 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Short-to- V_{DD} fault is detected on DOI4 when the high-side switch is in the off state. The FLatchEn bit in the Config1 register determines if this bit is real time (FLatchEn = 0) and cleared when the event disappears, or latched (FLatchEn = 1) and cleared when the ShtVDDChF register is read AND the fault condition is not present. |
| SHVDD3 | 2 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Short-to- V_{DD} fault is detected on DOI3 when the high-side switch is in the off state. |
| SHVDD2 | 1 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Short-to- V_{DD} fault is detected on DOI2 when the high-side switch is in the off state. |
| SHVDD1 | 0 | 0: Normal operating conditions 1: Only active in digital output high-side mode. Short-to- V_{DD} fault is detected on DOI1 when the high-side switch is in the off state. |

GlobalErr (0x07)

These bits are always latched, and are cleared on read provided that the diagnostic error is no longer valid at the time of reading the register.

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| Field | WDogErr | LossGND | ThrmShutd | VDD_UVLO | VDD_Warn | VDD_Low | V5_UVLO | VINT_UV |
| Reset | 0b0 | 0b0 | 0b0 | 0b1 | 0b1 | 0b1 | 0b1 | 0b1 |
| Access Type | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All | Read Clears All |

| BITFIELD | BITS | DESCRIPTION |
|-----------|------|---|
| WDogErr | 7 | 0: Normal operating conditions 1: SPI or SYNCH watchdog timeout is detected This bit takes effect when the SPI or SYNCH watchdog functions are enabled using the WDT0[1:0] and SynchWDEn bits in the Config2 register. This bit is part of the logical OR result of the ComErr bit in the Interrupt register. |
| LossGND | 6 | 0: Normal operating conditions 1: The MAX14906 detects loss of GND fault At power-on-reset, this bit can be 0 or 1. The microcontroller should ignore this initial setting until after it reads the GlobalErr register to clear this bit for normal operation. This bit is part of the logical OR result of the SupplyErr bit in the Interrupt register. |
| ThrmShutd | 5 | 0: Normal operating conditions 1: The MAX14906 enters thermal shutdown This bit is part of the logical OR result of the OverLdFault bit in the Interrupt register. |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| VDD_UVLO | 4 | 0: Normal operating conditions 1: V _{DD} supply falls under V _{DD_UVLO} threshold Set after power-on-reset. This bit can be cleared by reading the GlobalErr register when the V _{DD} voltage exceeds the V _{DD_UVLO} threshold. VDD_UVLO is part of the logic OR result of the SupplyErr bit in the Interrupt register if not disabled by the VDDFaultDis bit in the ConfigDI register. |
| VDD_Warn | 3 | 0: Normal operating conditions 1: V _{DD} supply falls below V _{DD_WARN} threshold Set after power-on-reset. This bit can be cleared by reading the GlobalErr register when the V _{DD} voltage exceeds the V _{DD_WARN} threshold. VDD_Warn is part of the logic OR result of the SupplyErr bit in the Interrupt register if not disabled by the VDDFaultDis bit in the ConfigDI register. It also asserts $\overline{\text{FAULT}}$ pin if not masked by the VddOKM bit in the Mask register. |
| VDD_Low | 2 | 0: Normal operating conditions 1: V _{DD} supply is below V _{DD_GOOD} threshold Set after power-on-reset. This bit can be cleared by reading the GlobalErr register when the V _{DD} voltage exceeds the V _{DD_GOOD} threshold. VDD_Low is part of the logic OR result of the SupplyErr bit in the Interrupt register if not disabled by the VDDFaultDis bit in the ConfigDI register. It also asserts $\overline{\text{FAULT}}$ pin if not masked by the VddOKM bit in the Mask register. |
| V5_UVLO | 1 | 0: Normal operating conditions 1: V ₅ voltage input falls under the V _{5_UVLO} threshold Set after power-on-reset. This bit can be cleared by reading the GlobalErr register when the V ₅ voltage exceeds the V _{5_UVLO} threshold. |
| VINT_UV | 0 | 0: Normal operating conditions 1: Set on initial power-up and when the internal supply to the registers falls to a level where the register contents are lost. This indicates that a power-on-reset has occurred and all register contents were reset. This bit can be cleared by reading the GlobalErr register when the internal register supply voltage (V _{INT}) exceeds the V _{TUV_INT} threshold. |

OpnWrEn (0x08)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|--------------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Field | GDrvEn4 | GDrvEn3 | GDrvEn2 | GDrvEn1 | OwOffEn4 | OwOffEn3 | OwOffEn2 | OwOffEn1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| GDrvEn4 | 7 | 0: Disable gate driver on G4 if not used to reduce power consumption 1: Enable gate driver for external pMOS transistor on G4 pin |
| GDrvEn3 | 6 | 0: Disable gate driver on G3 if not used to reduce power consumption 1: Enable gate driver for external pMOS transistor on G3 pin |
| GDrvEn2 | 5 | 0: Disable gate driver on G2 if not used to reduce power consumption 1: Enable gate driver for external pMOS transistor on G2 pin |
| GDrvEn1 | 4 | 0: Disable gate driver on G1 if not used to reduce power consumption 1: Enable gate driver for external pMOS transistor on G1 pin |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|---|
| OwOffEn4 | 3 | 0: Disable the pullup current source and open-wire detection on DOI4 1: Enable open-wire detection on DOI4 in DO high-side mode, off state |
| OwOffEn3 | 2 | 0: Disable the pullup current source and open-wire detection on DOI3 1: Enable open-wire detection on DOI3 in DO high-side mode, off state |
| OwOffEn2 | 1 | 0: Disable the pullup current source and open-wire detection on DOI2 1: Enable open-wire detection on DOI2 in DO high-side mode, off state |
| OwOffEn1 | 0 | 0: Disable the pullup current source and open-wire detection on DOI1 1: Enable open-wire detection on DOI1 in DO high-side mode, off state |

ShtVDDEn (0x09)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|-------------|
| Field | VDDOvEn4 | VDDOvEn3 | VDDOvEn2 | VDDOvEn1 | ShVddEn4 | ShVddEn3 | ShVddEn2 | ShVddEn1 |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 | 0b0 |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| VDDOvEn4 | 7 | 0: Disable V _{DD} OVLO detection on V _{DD4} 1: Enable V _{DD} OVLO detection (43.5V, typ) on V _{DD4} |
| VDDOvEn3 | 6 | 0: Disable V _{DD} OVLO detection on V _{DD3} 1: Enable V _{DD} OVLO detection (43.5V, typ) on V _{DD3} |
| VDDOvEn2 | 5 | 0: Disable V _{DD} OVLO detection on V _{DD2} 1: Enable V _{DD} OVLO detection (43.5V, typ) on V _{DD2} |
| VDDOvEn1 | 4 | 0: Disable V _{DD} OVLO detection on V _{DD1} 1: Enable V _{DD} OVLO detection (43.5V, typ) on V _{DD1} |
| ShVddEn4 | 3 | 0: Disable short-to-V _{DD} detection on DOI4 1: Enable short-to-V _{DD} detection on DOI4 |
| ShVddEn3 | 2 | 0: Disable short-to-V _{DD} detection on DOI3 1: Enable short-to-V _{DD} detection on DOI3 |
| ShVddEn2 | 1 | 0: Disable short-to-V _{DD} detection on DOI2 1: Enable short-to-V _{DD} detection on DOI2 |
| ShVddEn1 | 0 | 0: Disable short-to-V _{DD} detection on DOI1 1: Enable short-to-V _{DD} detection on DOI1 |

Config1 (0x0A)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|-------------|-------------|-------------|------------------|-------------|-------------|-------------|
| Field | LEDCurrLim | FLatchEn | FilterLong | FFilterEn | FLEDStretch[1:0] | SLEDSet | FLEDSet | |
| Reset | 0b0 | 0b1 | 0b0 | 0b1 | 0b00 | 0b1 | 0b1 | |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|------------|------|--|
| LEDCurrLim | 7 | If FLEDSet = 0, fault LEDs are controlled by internal FLED logic. LEDCurrLim controls whether fault LEDs signaling current limit faults. 0: Disable fault LEDs (FLEDs) signaling current limit 1: Enable fault LEDs (FLEDs) signaling current limit If FLEDSet = 1, fault LEDs are controlled by SetLED register. |

| BITFIELD | BITS | DESCRIPTION |
|-------------|------|---|
| FLatchEn | 6 | <p>0: Disable latching of diagnostic fault bits in the OvrLdChF, OpnWirChF, and ShtVDDChF registers 1: Enable latching of diagnostic fault bits in the OvrLdChF, OpnWirChF, and ShtVDDChF registers</p> <p>Faults in GlobalErr register are always latched regardless of the FLatchEn bit setting. SafeDemagF_ and VDDOKFault_ faults are always latched too. When the fault LEDs are controlled internally (FLEDSet = 0), the LED on-time is not affected by this bit, but has a minimum on-time defined by the FLEDStrech[1:0] bits. The fault LEDs are turned off when the faults disappear and minimum LED on-time expires as defined by the FLEDStrech[1:0] bits.</p> |
| FilterLong | 5 | <p>0: To select regular blanking time (4ms, typ) for diagnostic fault bits, OWOFF_ and SHVDD_ 1: To select long blanking time (8ms, typ) for diagnostic fault bits, OWOFF_ and SHVDD_ This bit also affects the fault LEDs (FLEDs) on-time when controlled internally (FLEDSet = 0).</p> |
| FFilterEn | 4 | <p>0: Disable blanking and filtering of the SHVDD_ and OWOFF_ diagnostic bits. In this mode, open-wire and short-to-V_{DD} diagnostics are real-time (only filtered by a 68μs (typ) filter) and any additional filtering is left to application software 1: Enable blanking and filtering of the SHVDD_ and OWOFF_ diagnostic bits</p> <p>When the fault LEDs (FLEDs) are controlled internally (FLEDSet = 0), open-wire and short-to-V_{DD} diagnostics always use filtering and cannot be disabled by the FFilterEn bit.</p> |
| FLEDStretch | 3:2 | <p>The FLEDStretch bits select the minimum on-time for the fault LEDs (FLEDs) when they are controlled internally (FLEDSet = 0), so the user can visually see short events.</p> <p>00: Disable minimum fault LED (FLED) on-time 01: Minimum fault LED (FLED) on-time = 1s (typ) 10: Minimum fault LED (FLED) on-time = 2s (typ) 11: Minimum fault LED (FLED) on-time = 3s (typ)</p> |
| SLEDSet | 1 | <p>0: All four status LEDs are controlled by the DOI1 to DOI4 status 1: All four status LEDs are controlled by the SLED_ bits in the SetLED register</p> |
| FLEDSet | 0 | <p>0: All four fault LEDs are controlled by the DOI1 to DOI4 fault diagnostics 1: All four fault LEDs are controlled by the FLED_ bits in the SetLED register</p> <p>Internal fault diagnostics include (if enabled): SafeDemagF_, SHVDD_, VDDOV_, OWOFF_, AboveVDD_, CL_, OVL_, VDDOKFault_.</p> |

Config2 (0x0B)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|--------------|---|----------------|---|-----------------------|-------------|
| Field | WDT0[1:0] | | OWOFFCs[1:0] | | ShtVddThr[1:0] | | SynchWDE _n | VDDOnThr |
| Reset | 0b00 | | 0b00 | | 0b00 | | 0b0 | 0b0 |
| Access Type | Write, Read | | Write, Read | | Write, Read | | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|-----------|------|--|
| WDT0 | 7:6 | 00: Disable SPI Watchdog Status and SPI Watchdog Timeout 01: Enable SPI Watchdog Status, set SPI and SYNCH Watchdog Timeout to 200ms (typ) 10: Enable SPI Watchdog Status, set SPI and SYNCH Watchdog Timeout to 600ms (typ) 11: Enable SPI Watchdog Status, set SPI and SYNCH Watchdog Timeout to 1.2s (typ) When the SPI watchdog is disabled, the SYNCH watchdog is configured by the SynchWDEn bit and the SYNCH watchdog timeout is set to 600ms (typ). |
| OWOffCs | 5:4 | The OWOffCs[1:0] bits select the pullup current used for the open-wire and short-to-V _{DD} detection when the switch is in the off state: 00: Set open-wire and short-to-V _{DD} detection current to 60µA (typ) 01: Set open-wire and short-to-V _{DD} detection current to 100µA (typ) 10: Set open-wire and short-to-V _{DD} detection current to 300µA (typ) 11: Set open-wire and short-to-V _{DD} detection current to 600µA (typ) |
| ShtVddThr | 3:2 | 00: Set threshold voltage for short-to-V _{DD} detection to 9V (typ) 01: Set threshold voltage for short-to-V _{DD} detection to 10V (typ) 10: Set threshold voltage for short-to-V _{DD} detection to 12V (typ) 11: Set threshold voltage for short-to-V _{DD} detection to 14V (typ) |
| SynchWDEn | 1 | 0: Disable the SYNCH Watchdog Status and Timeout 1: Enable the SYNCH Watchdog Status and Timeout The SYNCH watchdog timeout is defined by the WDT0[1:0] bits if the SPI watchdog is enabled. When WDT0[1:0] = 00 (SPI watchdog disabled), the SYNCH watchdog timeout is 600ms (typ) if enabled. |
| VDDOnThr | 0 | 0: Disable higher voltage thresholds for V _{DD} and V _{DD_} undervoltage monitoring 1: Enable higher voltage thresholds for V _{DD} and V _{DD_} undervoltage monitoring V _{DDOK} pin is asserted low and DOI_ channels automatically turn on when V _{DD} and V _{DD_} rise above the thresholds. See the Power-Up and Undervoltage Lockout section for details. The VDDOnThr bit affects per-channel VDDOKFault_ bits in the DoiLevel register when VDDFaultSel is set to 1. |

ConfigDI (0x0C)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------------|-------------|-------------|-----------------|-----------------|--------------------|------------------|---------------|---|
| Field | Typ2Di | Reserved | VDDFaultDi s | VDDFaultS el | AboveVDD ProtEn | OVLStretch En | OVLBlank[1:0] | |
| Reset | 0b0 | 0b0 | 0b0 | 0b0 | 0b1 | 0b0 | 0b00 | |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| Typ2Di | 7 | 0: Select IEC 61131-2 Type 1 and 3 in digital input mode 1: Select IEC 61131-2 Type 2 in digital input mode |
| Reserved | 6 | Reserved. Default value is 0. |

| BITFIELD | BITS | DESCRIPTION |
|----------------|------|--|
| VDDFaultDis | 5 | 0: Enable all V _{DD} and V _{DD} voltage level monitoring faults (VDD_UVLO, VDD_Warn, VDD_Low and VDDOKFault_) to be the source of the logic OR result of the SupplyErr bit in the Interrupt register 1: Mask all V _{DD} and V _{DD} voltage level monitoring faults (VDD_UVLO, VDD_Warn, VDD_Low and VDDOKFault_) to be the source of the logic OR result of the SupplyErr bit in the Interrupt register |
| VDDFaultSel | 4 | 0: Bits[3:0] in the DoiLevel register are per-channel DOI_ pin logic level 1: Bits[3:0] in DoiLevel register are per-channel VDDOK fault diagnostics for V _{DD} supply When VDDFaultSel = 0, the per-channel VDDOKFault_ bits are not mapped to the SupplyErr bit in the Interrupt register; hence, VDDOKFault_ bits do not generate an interrupt on the FAULT pin. |
| AboveVDDProtEn | 3 | 0: Disable Above-V _{DD} protection 1: Enable Above-V _{DD} protection. External pMOS transistors on G_ pins are turned-off when Above-V _{DD} fault is detected on DOI_ pins |
| OVLStretchEn | 2 | 0: Disable a 100ms (typ) minimum delay time to avoid channel thermal overload faults (OVL_ bits in the OvrLdChF register) toggling on and off when turning on a cold incandescent lamp 1: Enable a 100ms (typ) minimum delay time to avoid channel thermal overload faults (OVL_ bits in the OvrLdChF register) toggling on and off when turning on a cold incandescent lamp |
| OVLBlank | 1:0 | These bits select the blanking time for the OVL_ diagnostic bits in the OvrLdChF register and apply to all DOI_ channels no matter they are on or off. 00: Disable the blanking time for the OVL_ diagnostic bits 01: Set the OVL_ blanking time to 8ms (typ) 10: Set the OVL_ blanking time to 50ms (typ) 11: Set the OVL_ blanking time to 300ms (typ) |

ConfigDO (0x0D)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|--------------|---|--------------|---|--------------|---|--------------|---|
| Field | DoMode4[1:0] | | DoMode3[1:0] | | DoMode2[1:0] | | DoMode1[1:0] | |
| Reset | 0b00 | | 0b00 | | 0b00 | | 0b00 | |
| Access Type | Write, Read | | Write, Read | | Write, Read | | Write, Read | |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| DoMode4 | 7:6 | The DoMode4[1:0] bits select the digital output operating mode for DOI4. 00: High-side 01: High-side with 2x inrush current for t _{INRUSH} time (see CL4[1:0] bits for details) 10: Active-clamp push-pull 11: Simple push-pull |
| DoMode3 | 5:4 | The DoMode3[1:0] bits select the digital output operating mode for DOI3. 00: High-side 01: High-side with 2x inrush current for t _{INRUSH} time (see CL3[1:0] bits for details) 10: Active-clamp push-pull 11: Simple push-pull |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|---|
| DoMode2 | 3:2 | The DoMode2[1:0] bits select the digital output operating mode for DOI2. 00: High-side 01: High-side with 2x inrush current for t_{INRUSH} time (see CL2[1:0] bits for details) 10: Active-clamp push-pull 11: Simple push-pull |
| DoMode1 | 1:0 | The DoMode1[1:0] bits select the digital output operating mode for DOI1. 00: High-side 01: High-side with 2x inrush current for t_{INRUSH} time (see CL1[1:0] bits for details) 10: Active-clamp push-pull 11: Simple push-pull |

CurrLim (0x0E)

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------|-------------|---|-------------|---|-------------|---|-------------|---|
| Field | CL4[1:0] | | CL3[1:0] | | CL2[1:0] | | CL1[1:0] | |
| Reset | 0b00 | | 0b00 | | 0b00 | | 0b00 | |
| Access Type | Write, Read | | Write, Read | | Write, Read | | Write, Read | |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| CL4 | 7:6 | The CL4[1:0] bits set the current limit for DOI4 high-side transistor 00: Current Limit = 600mA (typ), t_{INRUSH} = 20ms (typ) 01: Current Limit = 130mA (typ), t_{INRUSH} = 50ms (typ) 10: Current Limit = 300mA (typ), t_{INRUSH} = 40ms (typ) 11: Current Limit = 1.2A (typ), t_{INRUSH} = 10ms (typ) |
| CL3 | 5:4 | The CL3[1:0] bits set the current limit for DOI3 high-side transistor 00: Current Limit = 600mA (typ), t_{INRUSH} = 20ms (typ) 01: Current Limit = 130mA (typ), t_{INRUSH} = 50ms (typ) 10: Current Limit = 300mA (typ), t_{INRUSH} = 40ms (typ) 11: Current Limit = 1.2A (typ), t_{INRUSH} = 10ms (typ) |
| CL2 | 3:2 | The CL2[1:0] bits set the current limit for DOI2 high-side transistor 00: Current Limit = 600mA (typ), t_{INRUSH} = 20ms (typ) 01: Current Limit = 130mA (typ), t_{INRUSH} = 50ms (typ) 10: Current Limit = 300mA (typ), t_{INRUSH} = 40ms (typ) 11: Current Limit = 1.2A (typ), t_{INRUSH} = 10ms (typ) |
| CL1 | 1:0 | The CL1[1:0] bits set the current limit for DOI1 high-side transistor 00: Current Limit = 600mA (typ), t_{INRUSH} = 20ms (typ) 01: Current Limit = 130mA (typ), t_{INRUSH} = 50ms (typ) 10: Current Limit = 300mA (typ), t_{INRUSH} = 40ms (typ) 11: Current Limit = 1.2A (typ), t_{INRUSH} = 10ms (typ) |

Mask (0x0F)

Disabling the mask (setting the bit = 0) enables the fault source to assert the $\overline{\text{FAULT}}$ pin output.
Enabling the mask (setting the bit = 1) disables the fault source to assert the $\overline{\text{FAULT}}$ pin output.

| BIT | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|----------------|-------------|-------------|-------------|-------------|---------------|-------------|-------------|-------------|
| Field | ComErrM | SupplyErrM | VddOKM | ShtVddM | AboveVDD M | OwOffM | CurrLimM | OverLdM |
| Reset | 0b1 | 0b0 | 0b1 | 0b1 | 0b1 | 0b1 | 0b1 | 0b0 |
| Access Type | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read | Write, Read |

| BITFIELD | BITS | DESCRIPTION |
|------------|------|---|
| ComErrM | 7 | <p>0: Disable masking of watchdog error and SPI/CRC error bits on the $\overline{\text{FAULT}}$ pin 1: Enable masking of watchdog error and SPI/CRC error bits on the $\overline{\text{FAULT}}$ pin</p> <p>Independent of this bit setting, the error conditions are flagged using the ComErr bit in the Interrupt register and the GLOBF bit in the SDO data packet.</p> |
| SupplyErrM | 6 | <p>0: Disable masking of supply errors on the $\overline{\text{FAULT}}$ pin 1: Enable masking of supply errors on the $\overline{\text{FAULT}}$ pin</p> <p>Independent of this bit, the error conditions are flagged using the SupplyErr bit in the Interrupt register and the GLOBF bit in the SDO data packet.</p> |
| VddOKM | 5 | <p>0: Disable masking of VDD_Low and VDD_Warn errors on the $\overline{\text{FAULT}}$ pin 1: Enable masking of VDD_Low and VDD_Warn errors on the $\overline{\text{FAULT}}$ pin</p> <p>The SupplyErr bit is always active and not affected by this bit setting. See Figure 6 for details.</p> |
| ShtVddM | 4 | <p>0: Disable masking of short-to-V_{DD} error on the $\overline{\text{FAULT}}$ pin 1: Enable masking of short-to-V_{DD} error on the $\overline{\text{FAULT}}$ pin</p> <p>If the short-to-V_{DD} detection is enabled in the ShtVDDEn register, short-to-V_{DD} conditions are signaled in the SHVDD_ bits in the ShtVDDChF register, and the SHTVDD bit in the SPI SDO data.</p> |
| AboveVDDM | 3 | <p>0: Disable masking of above-V_{DD} error on the $\overline{\text{FAULT}}$ pin 1: Enable masking of above-V_{DD} error on the $\overline{\text{FAULT}}$ pin</p> <p>If the above-V_{DD} detection is enabled in the ShtVDDEn register, above-V_{DD} conditions are signaled in the AboveVDD_ bits in the OpnWirChF register, and the AbvVDD bit in the SPI SDO data.</p> |
| OwOffM | 2 | <p>0: Disable masking of open-wire in off-state error on the $\overline{\text{FAULT}}$ pin 1: Enable masking of open-wire in off-state error on the $\overline{\text{FAULT}}$ pin</p> <p>If the open-wire detection in off state is enabled by the OwOffEn_ bits in the OpnWrEn register, the open-wire detection in off state is signaled by the OWOff_ bits in the OpnWirChF register and the OWOff bit in the SPI SDO data.</p> |
| CurrLimM | 1 | <p>0: Disable masking of current limit error on the $\overline{\text{FAULT}}$ pin 1: Enable masking of current limit error on the $\overline{\text{FAULT}}$ pin</p> <p>Independent of this bit setting, current limit conditions are always signaled by the CL_ bits in the OvrLdChF register and the OvrCurr bit in the SPI SDO data.</p> |

| BITFIELD | BITS | DESCRIPTION |
|----------|------|--|
| OverLdM | 0 | 0: Disable masking of thermal overload error on the $\overline{\text{FAULT}}$ pin 1: Enable masking of thermal overload error on the $\overline{\text{FAULT}}$ pin Independent of this bit setting, thermal overload faults are always signaled by the OVL_ bits in the OvrLdChF register and the OvldF bit in the SPI SDO data. |

Applications Information

Configurable DO/DI

The [Typical Application Circuits](#) illustrates two quad isolated configurable digital-output/digital-input circuits that are fully IEC 61131-2 compliant.

The external pMOS transistors protect the MAX14906 from V_{DD} reverse polarity miswiring on the V_{DD} supplies. In DI mode, the external pMOS transistor is permanently turned off through the gate output (G_{-}), allowing DOI_{-} input to be higher than the V_{DD} supply voltage. When the DOI_{-} voltage is lower than the V_{DD} voltage minus one diode drop, the MAX14906 is powered through V_{DD} through the body diode of the external pMOS transistor.

Power Supply Sequencing

The MAX14906 is flexible, and does not require any specific power-up sequence for its supplies.

At power-up, the default register settings configure the device into digital output high-side mode. Thus, if the D_{-} logic pins are high at power-up, for example due to pullup resistors, the associated DOI_{-} outputs switch on if the EN and the SYNCH logic inputs also are high.

To avoid the DOI_{-} switches turning on at power-up, the following should be considered:

- If the device is operated in serial mode, connect all D_{-} pins low.
- When operated in pin-control mode, during which the D_{-} logic pins are used, ensure that either the EN, the SYNCH, or the D_{-} pins are logic low at power-up.

External V_5 Power

The MAX14906 requires a 5V power supply on V_5 and can be powered either by the internal 5V linear regulator if REGEN is unconnected; or can be powered by an external 5V supply. If powering V_5 from an external regulator, connect REGEN to GND.

Driving Capacitive Loads

When charging and discharging purely capacitive loads with a push-pull driver, the driver dissipates power that is proportional to the switching frequency. The power can be estimated by

$$P_D = C_L \times V_{DD}^2 \times f$$

where,

C_L = Load capacitance

V_{DD} = Supply voltage

f = Switching frequency in Hz.

For example, a pure 10nF capacitive load switching at 100kHz with a 24V supply would result in approximately 580mW dissipation in the push-pull driver. Hence the capacitors connected to DOI_{-} for EMC purposes should be held with as small a capacitance as possible, if high switching rates are expected. Resistance placed in series with the capacitance reduces the power dissipation in the driver.

Driving Inductive Loads

When an inductive load is turned off by opening the high-side switch, the DOI_{-} pins go to a negative voltage in both high-side and active-clamp push-pull modes. The MAX14906 features an internal active clamp that clamps inductive energy at -55V (typ) relative to V_{DD} , which allows inductive load currents to decay quickly.

The inductive energy is dissipated in the active clamp. If the inductance is large and/or the inductive load current is large, the clamping energy is high. If this dissipation energy is too high, it could cause damage to the IC. The MAX14906 features Maxim's patented SafeDemag technology, allowing unlimited inductive energy to be demagnetized for load currents up to 600mA. Refer to [Application Note 6307](#) for details. For load currents above 600mA, the inductive clamping energy must be limited to 0.3 Joule. For higher inductive clamping energies, an external Zener/TVS clamping diode must be used on the DOI_{-} pin. Ensure that the external TVS/zener clamps at a voltage (V_Z) lower than the internal active

clamp (V_{CL}) and that the external zener diode is able to dissipate the clamping energy.

Reverse Current into DOI

If current flows into a DOI_n pin, the device heats up due to the internal current that flows through the device from V_{DD_n} to PGND. The internal current is proportional to the reverse input current flowing into DOI_n. The allowed reverse current depends on V_{DD_n} voltage, the ambient temperature, and the package thermal resistance (θ_{JA}). At an ambient temperature of 25°C, limit the reverse current into a DOI_n pin to 1A at $V_{DD_n} = 36V$ and 2A at $V_{DD_n} = 24V$.

To protect the device from reverse currents, connect an external pMOS transistor in series to the V_{DD_n} supplies (see the [Typical Application Circuits](#) for details), and turn on the transistors by setting the GDrvEn_n bits in the OpnWrEn register to high.

The MAX14906 has an above- V_{DD} comparator. After an above- V_{DD} fault is detected and a 200 μ s (typ) debounce time, the AboveVDD_n bits in the OpnWirChF register are set. When the AboveVDD_n faults are asserted and the device is in digital output mode, the external pMOS transistors are turned off and high-side switches are turned off if the above- V_{DD} protection feature is turned on (AboveVDDProtEn = 1). AboveVDD_n faults are latched and need to be cleared before the high-side switch can be turned on.

When a DOI_n channel is in digital input mode including the high-impedance low-leakage mode, the external pMOS transistor is always off and G_n pin is shorted to V_{DD_n} . In this case, the current consumption is very low and the channel is supplied through the external pMOS FET body diode.

When the GDrvEn_n bits are 0, the external pMOS transistor gate drivers (G_n) are always off to save current consumption. The device is not protected for reverse current. If the above- V_{DD} faults are detected, the AboveVDD_n bits are set after 200 μ s (typ) debounce time, but no actions are taken on the DOI_n channels.

Surge Protection

Without external protection devices, the DOI_n channels are protected against negative 1kV surges per IEC 61000-4-5 (42 Ω /0.5 μ F). A suppressor/TVS diode should be applied between the V_{DD} pin and GND to clamp positive surge transients on the DOI_n pins. The TVS standoff voltage should be higher than the maximum operating voltage of the equipment while the breakdown voltage should be below 65V.

ESD Protection

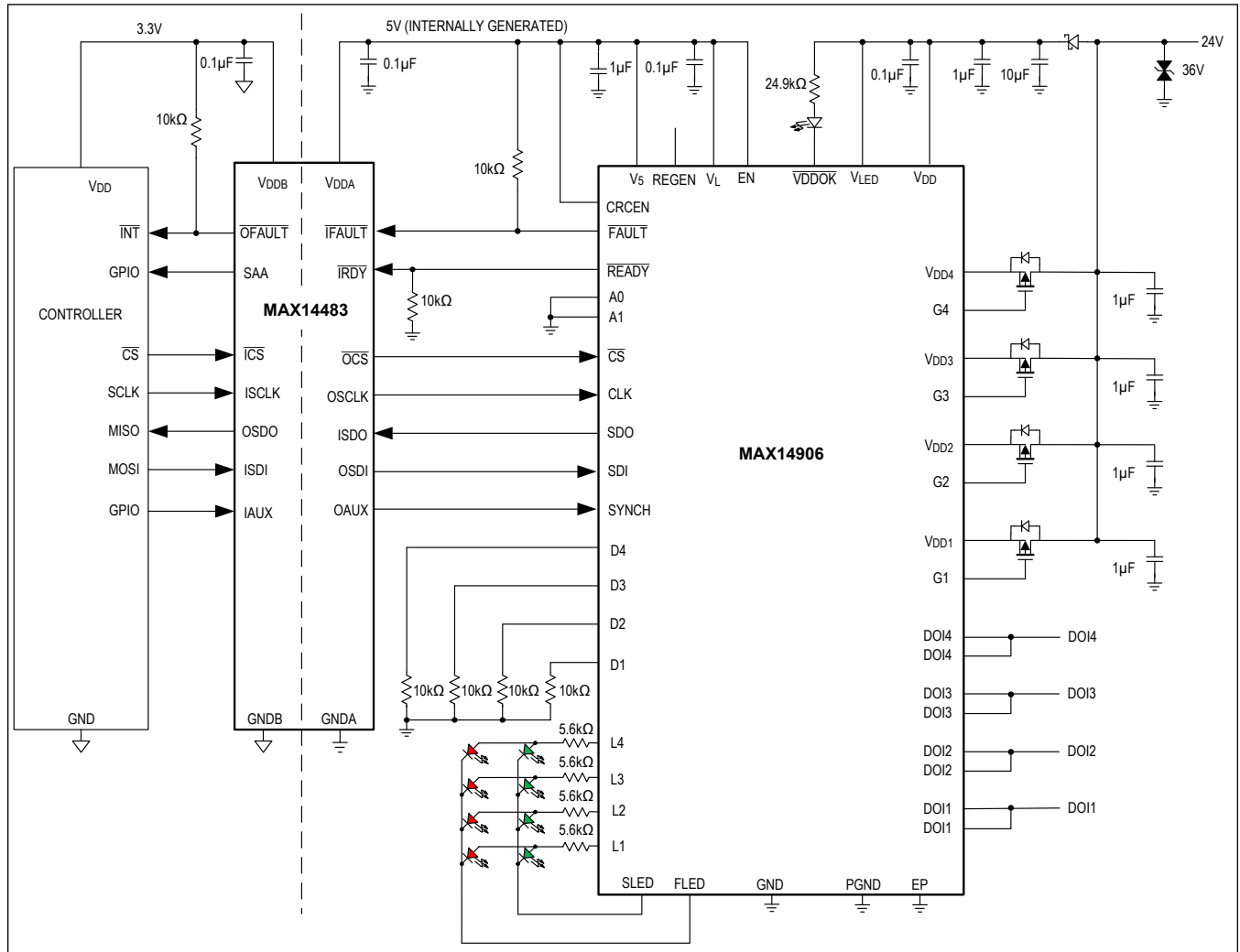
To protect the MAX14906 from an electrostatic discharge (ESD) event per IEC 61000-4-2, an additional 470pF is recommended on each DOI_n to PGND. Also, an additional 1 μ F bypass capacitor should be placed as close to each V_{DD_n} pin as possible.

Table 8. Recommended Components

| COMPONENT | DESCRIPTION | REQUIRED/RECOMMENDED/OPTIONAL |
|-----------|---|-------------------------------|
| C1 | 470pF, 100V, ceramic capacitor on each DOI _n pin | Required (ESD) |
| C2 | 1 μ F, 100V, ceramic capacitor on each V_{DD_n} pin | Required (ESD) |
| D1 | TVS diode (SMBJ36CA) on the V_{DD} pin | Required (Surge) |
| Q1 | P-channel transistor (NTTFS5116PLTAG) on each V_{DD_n} pin | Reverse Current Protection |

Typical Application Circuit (continued)

Quad Isolated DO/DI with SPI only Control



Ordering Information

| PART NUMBER | TEMP. RANGE | PIN PACKAGE | LEAD PITCH |
|---------------|-----------------|---------------|------------|
| MAX14906ATM+ | -40°C to +125°C | 7 x 7 TQFN-48 | 0.5mm |
| MAX14906ATM+T | -40°C to +125°C | 7 x 7 TQFN-48 | 0.5mm |

+ Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

Revision History

| REVISION NUMBER | REVISION DATE | DESCRIPTION | PAGES CHANGED |
|-----------------|---------------|--|----------------|
| 0 | 1/20 | Initial release | — |
| 1 | 2/20 | Updated the SetOUT (0x00) Register | 37 |
| 2 | 8/21 | Updated <i>Digital Input Operation</i> section, Figure 11, and <i>Configurable DO/DI</i> section | 16, 30, 51 |
| 3 | 2/22 | Updated <i>Electrical Characteristics</i> Table and <i>Typical Operating Characteristics</i> | 4, 10, 11 |
| 4 | 4/22 | Updated <i>Absolute Maximum Ratings</i> section, <i>Electrical Characteristics</i> Table, <i>Configurable DO/DI</i> section, Table 8, and <i>Typical Application Circuit</i> section | 3, 4, 7, 53–56 |